

“Direct Diode”: History, Trends and Limits of Power Photonics

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Harder&Partner

Engelberg Lectures, 2009

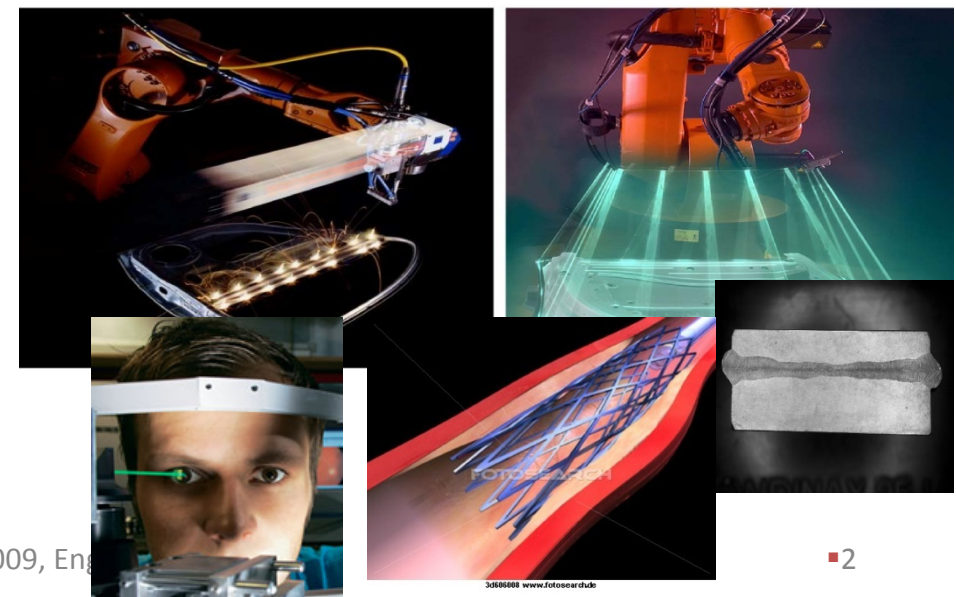
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Direct Diode

1. Internet is powered up by pump diode lasers.
 - All long distance links have Erbium Doped Fiber Amplifier (EDFAs)
 - Pump diode lasers to energize the EDFA
 - Compact, solid state efficiency and reliability



2. Power Photonics
 - Today: Classical lasers
 - Will be replaced by
 - Direct diode
 - Diode pumped fiber lasers
 - Compact, solid state efficiency and reliability



Acknowledgement

Acknowledgement

Dr. Dominik Jaeggi, Bookham , Dr. Toby Strite, JDSU, Dr. Alex Ovtchinnikov, IPG, Dr. Berthold Schmidt, Intense,
Dr. Michael Lebby, OIDA

Literature

Christoph Harder; “Chapter: Pump Diode Lasers”, Optical Fiber Telecommunications V A (Fifth Edition),
Components and Subsystems, Editor: *Ivan P. Kaminow, Tingye Li and Alan E. Willner*, pp. 107-144.

Swisslaser.net download Photonics 2008 Shortcourse

Telecom Pump Diode Lasers

EDFA: Demonstrated 20 years ago

LOW-NOISE ERBIUM-DOPED FIBRE AMPLIFIER OPERATING AT 1.54 μm

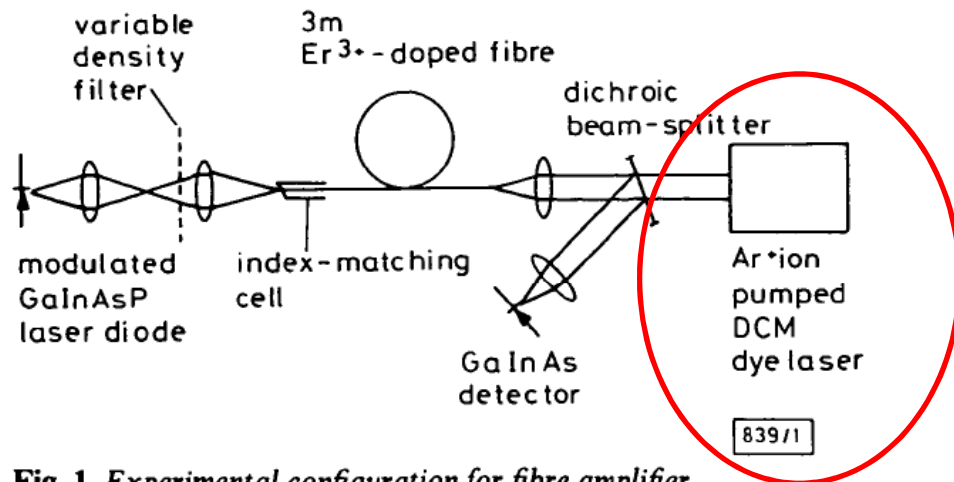


Fig. 1 Experimental configuration for fibre amplifier

- All optical silica fibre amplifier at wavelength window of lowest loss. Low noise
- Dye laser pump source
- Prof. Payne had prior to this publication alluded to EDFA in *Elect. Lett.* in 1985

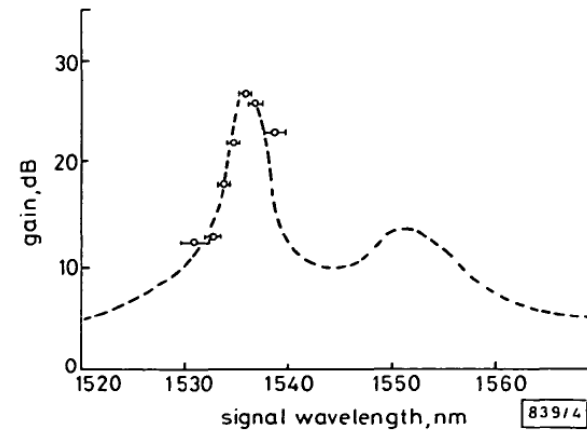


Fig. 4 Gain spectrum and spontaneous emission

Points represent experimental measurements and error bars indicate spectral width of diode laser spectrum
Curve represents fluorescence curve

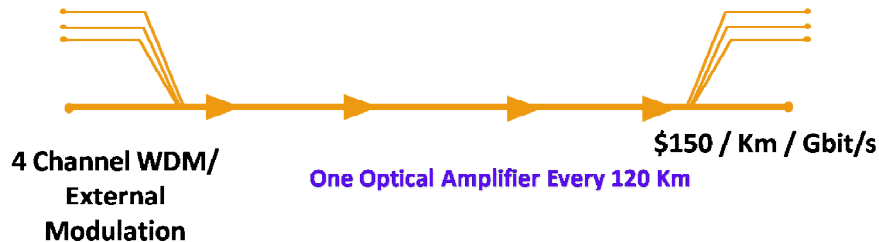
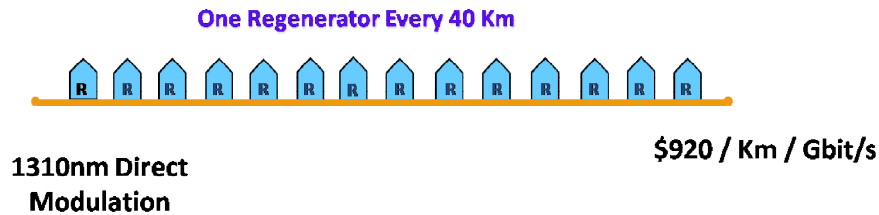
R. J. MEARS*
L. REEKIE
I. M. JAUNCEY
D. N. PAYNE

3rd August 1987

Optical Fibre Group
Department of Electronics
University of Southampton
Southampton SO9 5NH, United Kingdom

IBM Research Laboratory: 980 Diode Laser

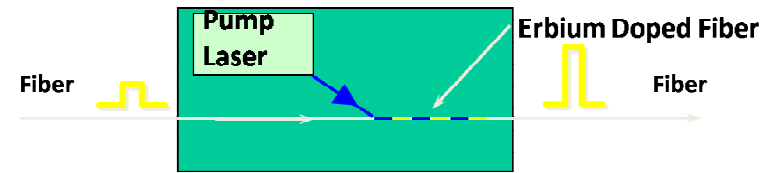
Disruptive Technology:



- Today:
- A few hundred channels at 10Gb/s over a few thousand km!

Magic Fiber: Erbium doped fiber

Optical Amplifier



Optical Amplifier:

980nm pump laser as power supply
We were the only laser supplier for high power and high reliability

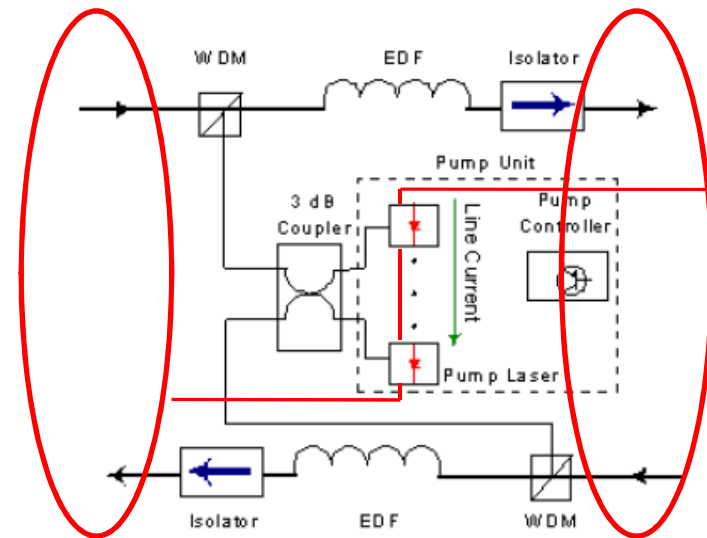
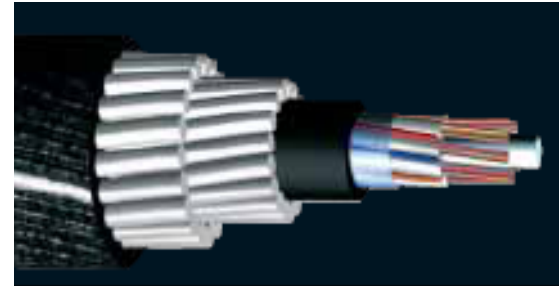
Example: Intercontinental

TAT-8 (1988): 0.28Gb/s per fiber
46k\$/channel
TGN (2004): 1000Gb/s per fiber
12\$/channel

EDFA Repeated Transmission

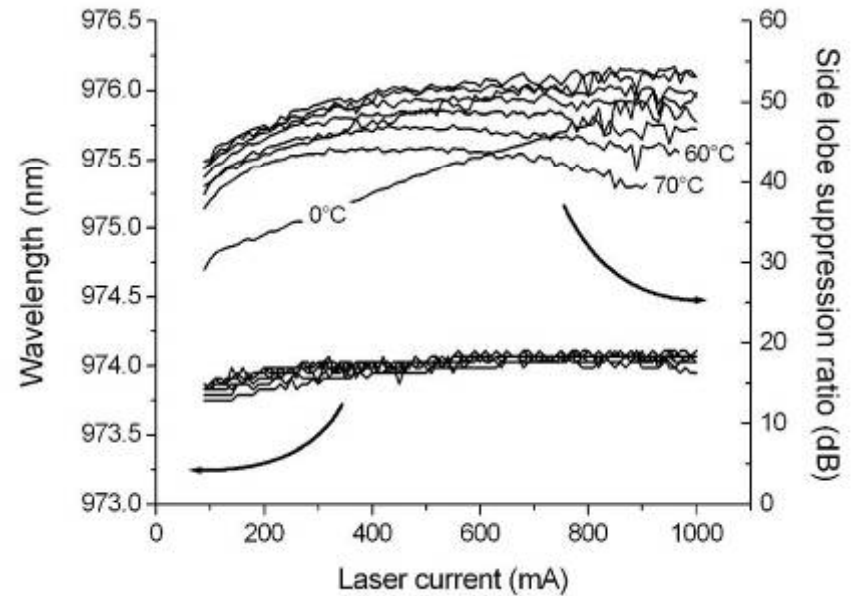
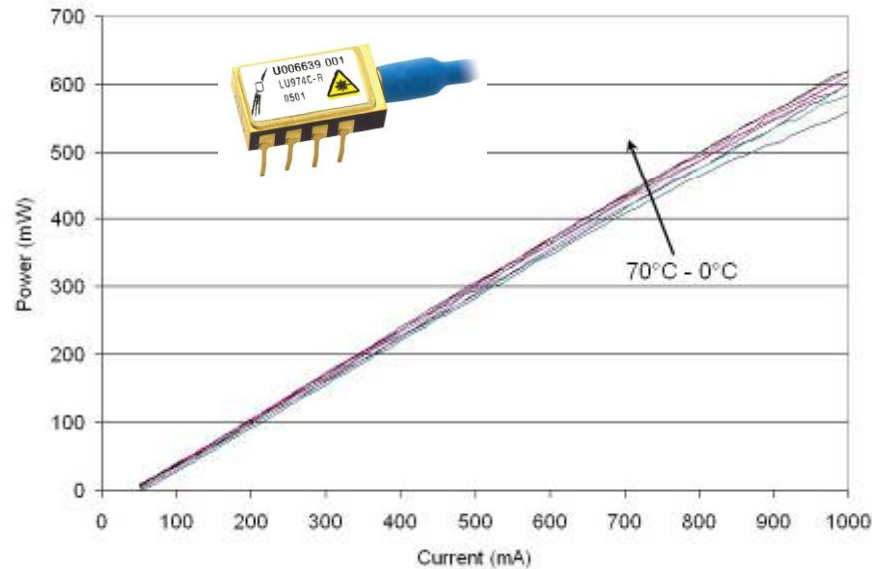
1. Intercontinental Lines
 - Typically submerged cables
 - 64*10Gb/s over 6000km
 - EDFA every 50km
 - 10.. 70 fiber pairs per cable
2. Long distance links
 - Landlines
3. TV Distribution
 - Power amplifier before splitting lines to broadcast TV signal through many fibers

Alltogether: A few million pump lasers powering up these links



Narrow Stripe Single Mode Fiber Pump Module

- 600 mW Power at 1 A operating current
- Wavelength locked by FBG over 70 K with high side lobe suppression ratio



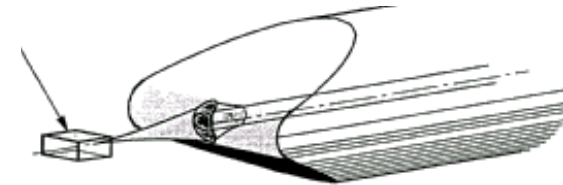
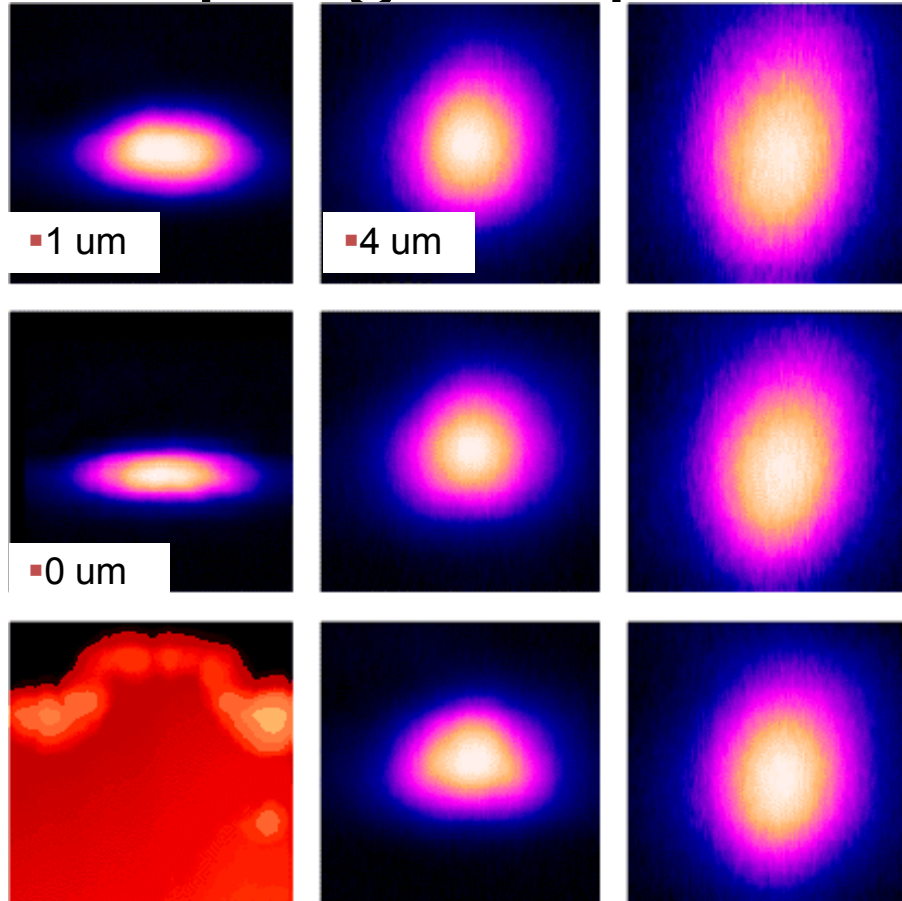
Different Pump Wavelength for Communication

Figure of Merit	980nm SM EDFA	940nm MM YEDFA	1480nm SM EDFA	14xxnm Raman	Comments
Noise	Very good	Good	OK	Excellent	
Max Output Power	Good	Excellent	Good	na	
Wallplug conversion efficiency	5%..15% (uncooled)	10%..15%	2%	1%	Output/Input Power
Gain flatness	Good	Poor	Good	OK	
Bandwidth	Wide (C+L)	Poor	Wide (C+L)	Excellent	
Reliability	Excellent	OK	Excellent	Excellent	
Max temperature	T<75C	T<45C	T<70C	T<70C	
Packaging	Simple	Simple	Lens Isolator	Simple	Cost
System embedding	Easy	Easy	Easy	Difficult	
Application	Generic	CATV Booster	Use only as remote preamp	Use for expansion beyond C and L band	

1. 9xx
 - Dominant technology for internet, CATV
2. 1480 and 14xx
 - Today for niche applications (remote EDFA and Raman)

Cost: Dominated by coupling pump diode beam to fiber

Narrow Stripe Coupling Pump Diode Beam to Fiber



Single Mode Fiber: $NA=0.12$

Laser Diode:

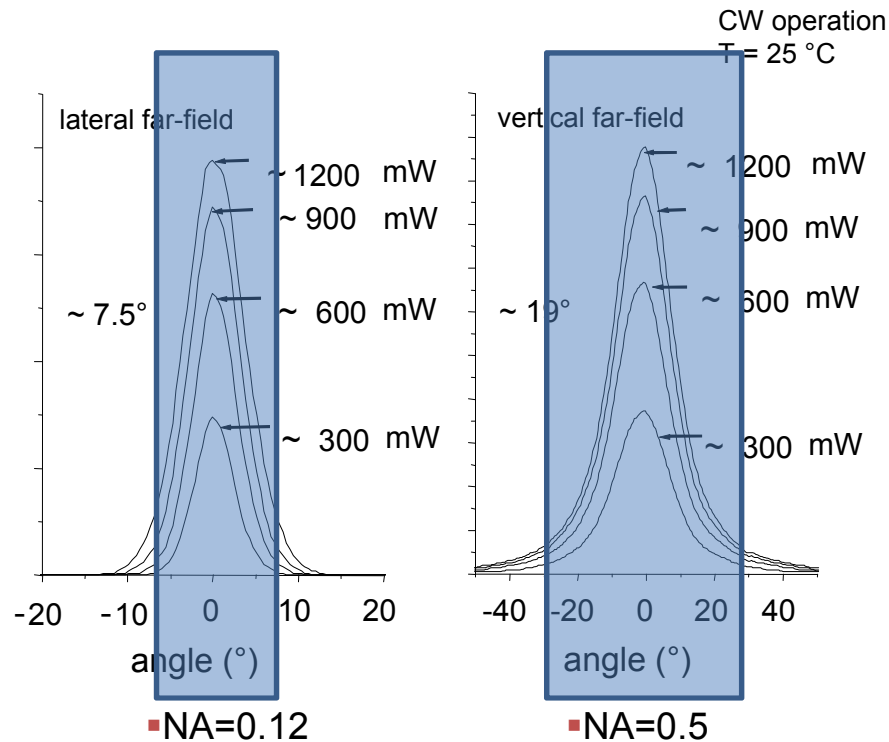
- In slow axis: $NA=0.12$, matched to NA of fiber
- In fast axis: $NA=0.5$, polish lens on fiber tip

Coupling

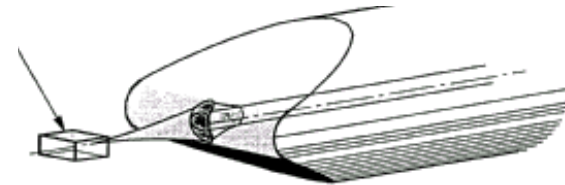
- At distance of 4um: Profiles match

Prof. Unlü, Boston

Narrow Stripe Coupling Pump Diode Beam to Fiber



- $NA = \sin(\text{angle}) \sim \text{angle}$
- Slow axis: $NA = 0.12 \sim 7\text{deg}$
- Fast axis: $NA = 0.5 \sim 30\text{deg}$



Single Mode Fiber: $NA = 0.12$

Coupling: NA matching

- Laser diode in slow axis: $NA = 0.12$, matched to NA of fiber
- Laser diode in fast axis: $NA = 0.5$, polish lens on fiber tip to match to $NA = 0.12$ of the fiber

Narrow Stripe NA design of waveguide

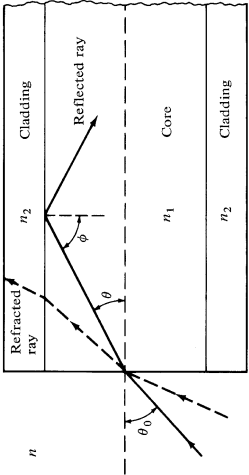
Pump Diode is dielectric waveguide with index n_1 , n_2 and NA

$$NA = (n_1^2 - n_2^2)^{1/2} \approx \sqrt{2 \cdot dn \cdot n}$$

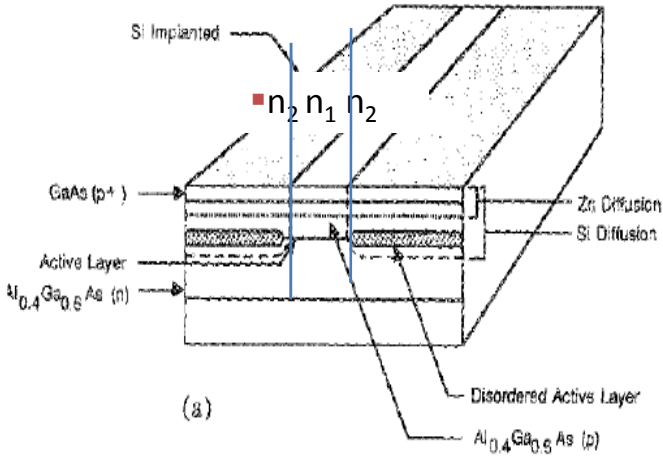
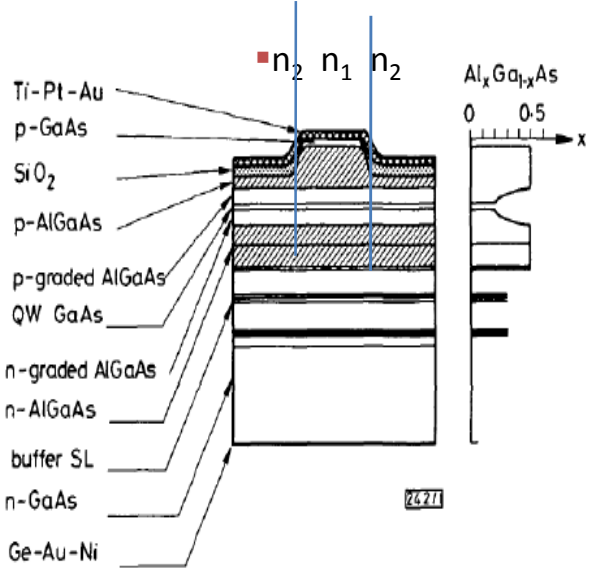
$$dn = n_1 - n_2$$

$$dn = \frac{1}{2} \cdot \left(\frac{NA}{n}\right)^2$$

$$\rightarrow dn = 5 \cdot 10^{-4} \quad (NA = 0.12 \text{ and } n = 3.6)$$

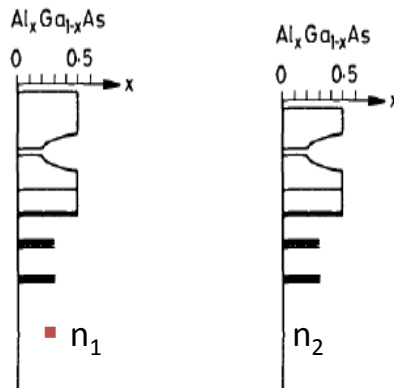
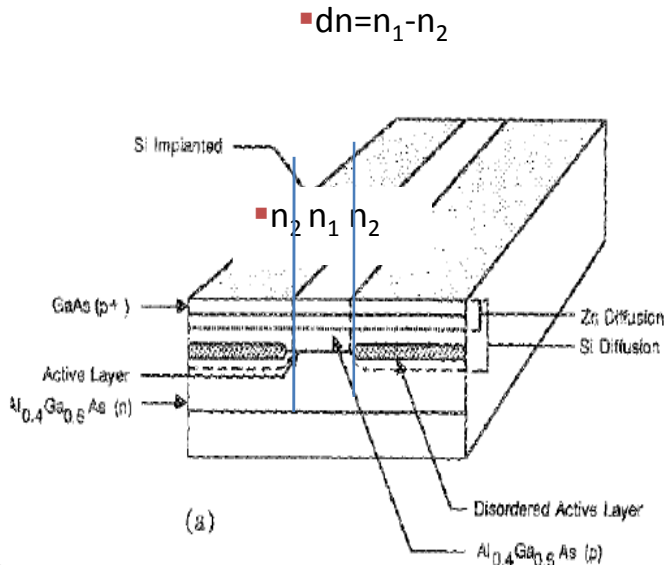
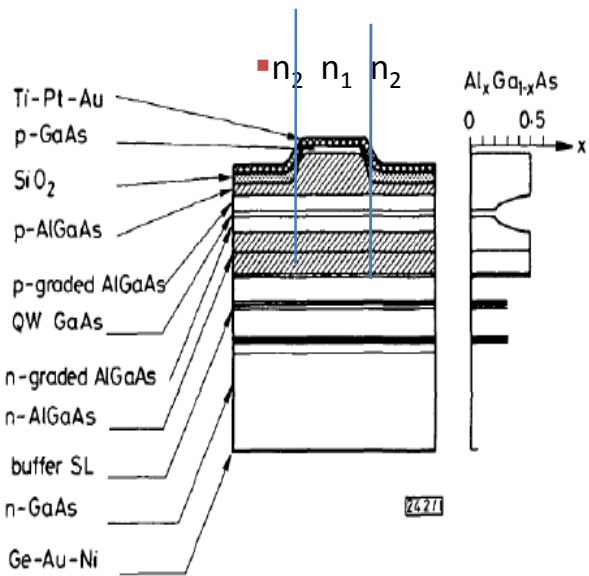


Need a weak waveguide: Ridge or disordered



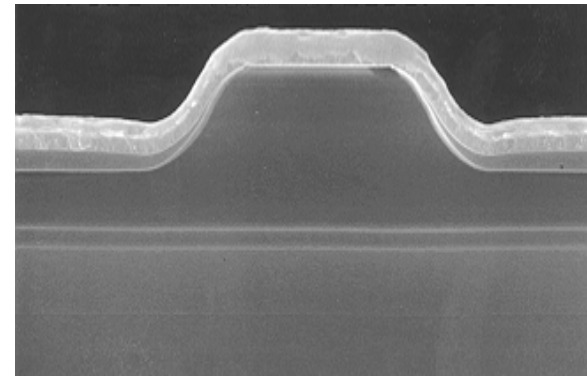
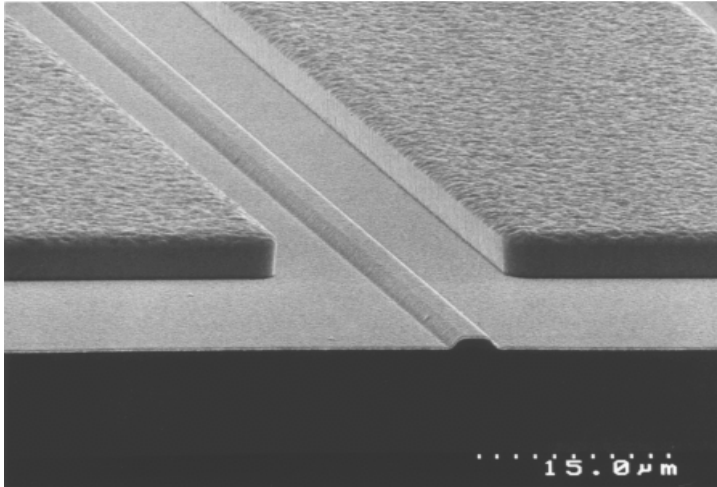
Pump Diode Beam: Slow axis

Effective Index approach

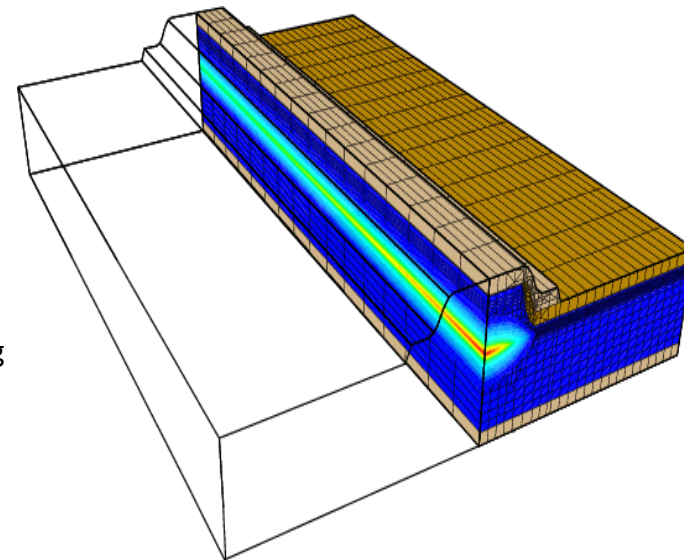


- Effective Index approach
 - Calculate effective index of planar waveguides (center and outside)

Narrow Stripe Ridge waveguide

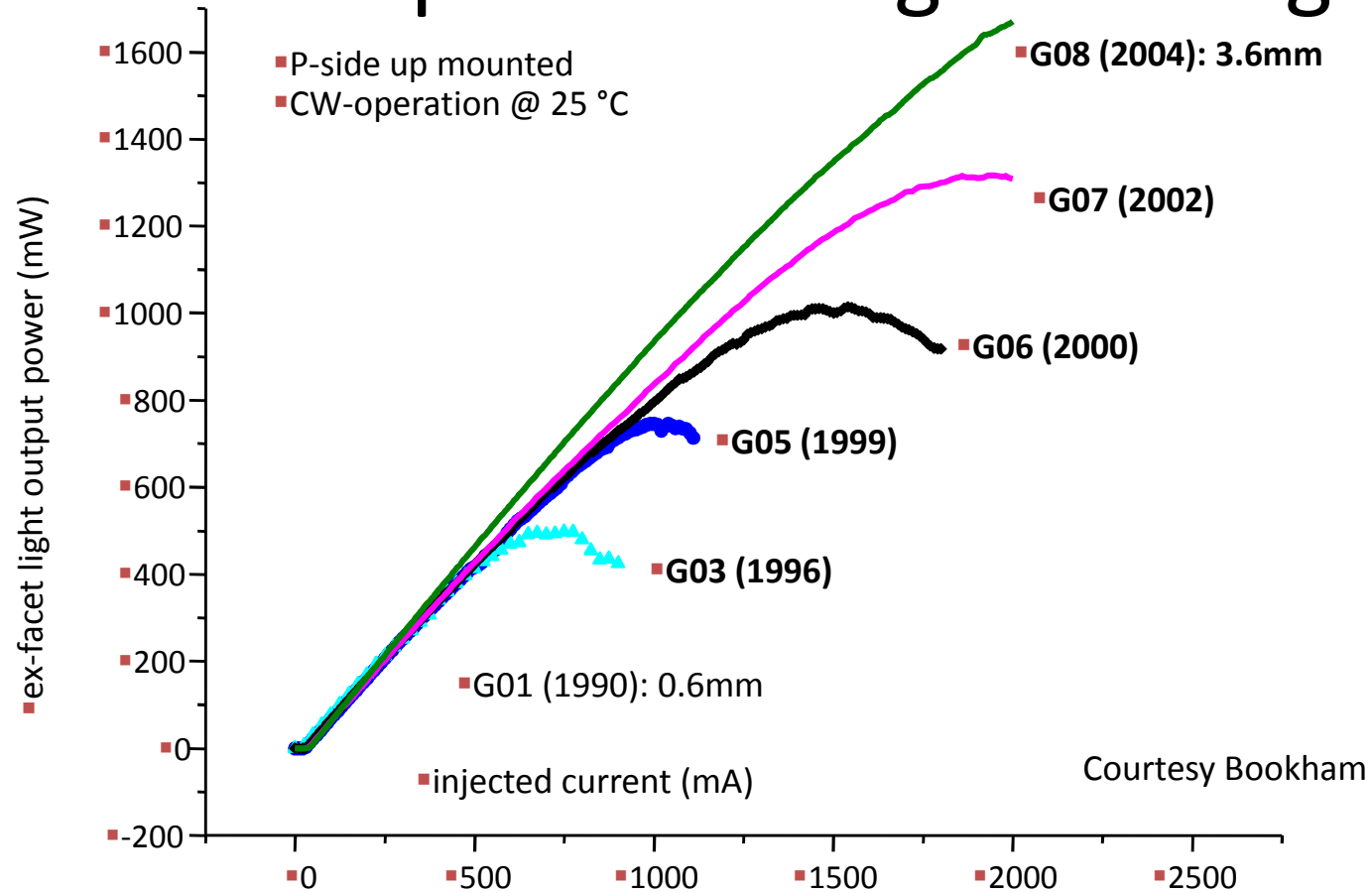


- Ridge Waveguide
 - One growth step, simple process
 - Built in reliability
 - InGaAlAs for best material properties
 - Confinement
 - Index guided mode: High linear power and excellent coupling to fiber
 - Temperature insensitive current confinement
 - Scalability
 - Increase power by making chip longer



Narrow Stripe

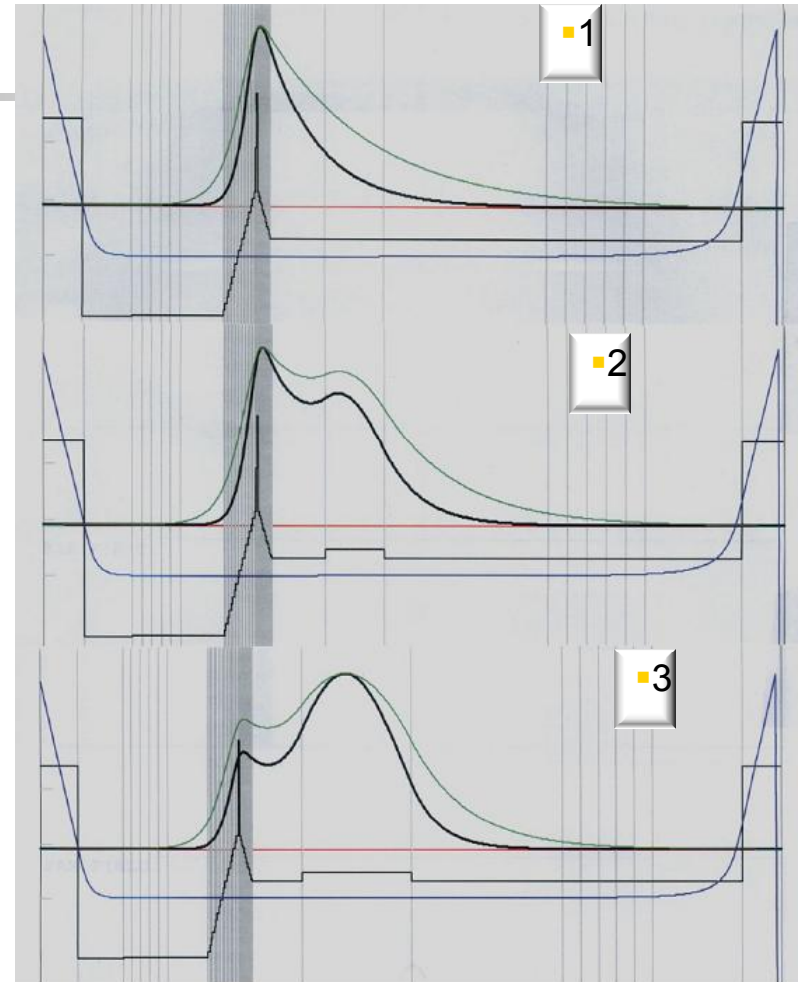
980nm Pump Diode Length Scaling



Improve performance by length scaling

Epi structures with low Γ

- Asymmetric, with optical trap on n side
- 1.7 times decrease in Γ (from 1 to 2) by using the trap
- Γ is changed by only changing the trap width (2 & 3) – easy execution
- Advantages:
 - Lower attenuation coefficient
 - Lower thermal resistance
 - Narrow FF



■ Dr. Julian Petrescu-Prahova

Narrow Stripe

Length Scaling (Dilute waveguides)

- **Increase power: Make laser longer to better remove the heat.**
 - Most important laser parameters:
 - Gain(G), efficacy(η), photon lifetime (τ_{ph}), internal power ratio (Pr)

$$G = \left(\alpha + \frac{1}{2L} * \ln\left(\frac{1}{R}\right) \right) / \Gamma, \quad \eta = \left(\frac{1}{2L} * \ln\left(\frac{1}{R}\right) \right) / \left(\alpha + \frac{1}{2L} * \ln\left(\frac{1}{R}\right) \right)$$

$$\tau_{ph} = 1 / \left(v_{gr} * \left(\alpha + \frac{1}{2L} * \ln\left(\frac{1}{R}\right) \right) \right), \quad Pr = (1 + R) / (2 * \sqrt{R})$$
 - absorption(α), length(L), confinement (Γ), front mirror reflectivity R (backmirror reflectivity=1)

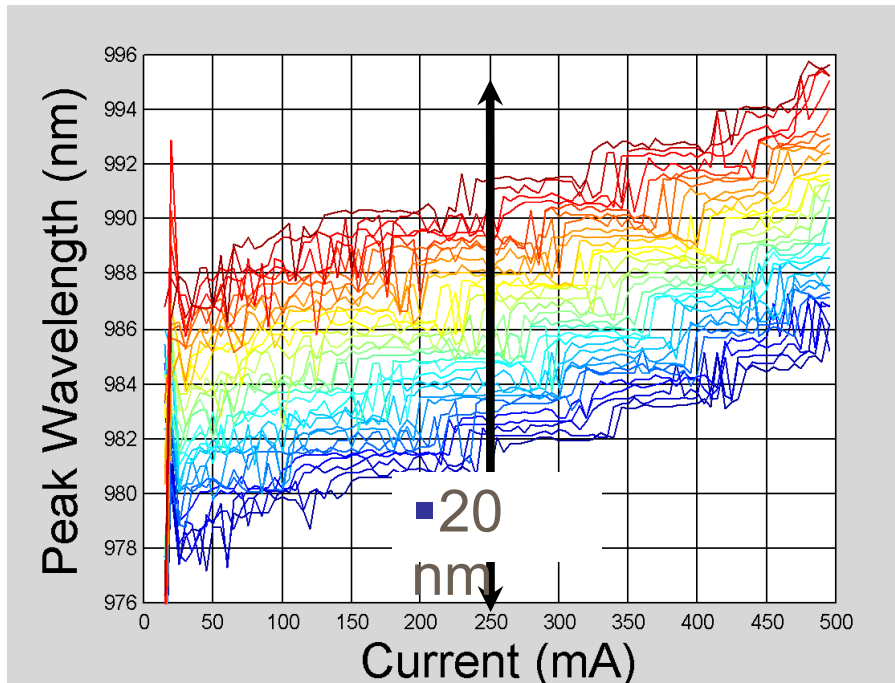
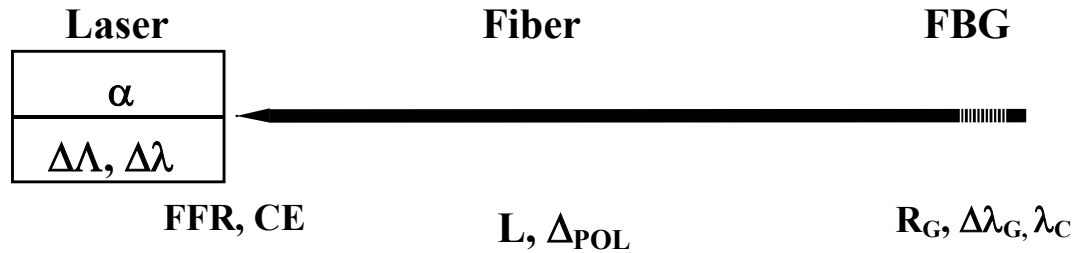
- Keep Gain(G), efficacy(η), and internal power ratio (Pr) constant
 - > Scaling rule for R, Γ and α for lasers with length L

$$R(L) = R(L_0) \quad \Gamma(L) = \frac{L_0}{L} * \Gamma(L_0), \quad \alpha(L) = \frac{L_0}{L} * \alpha(L_0)$$

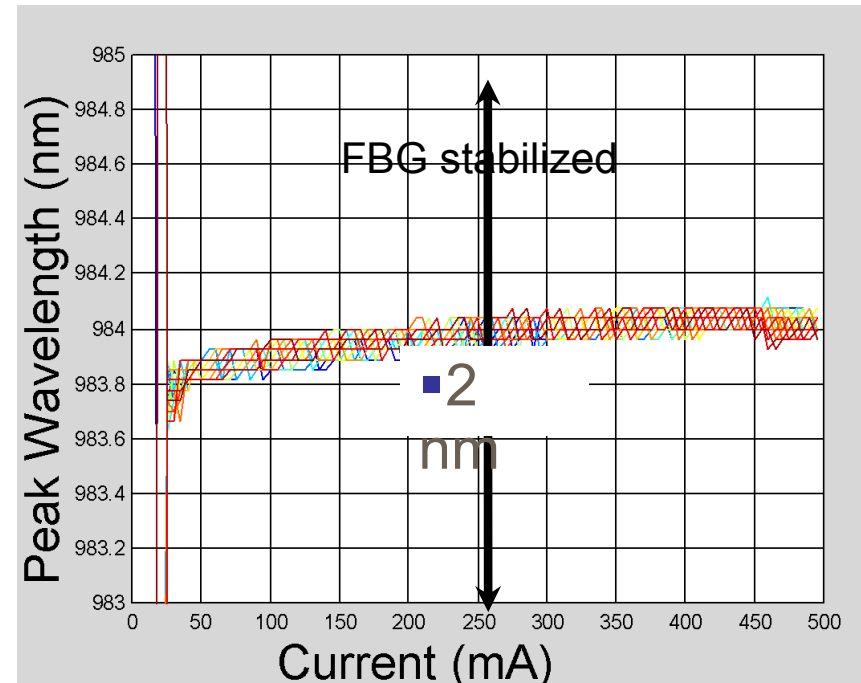
- **Output power scales then linearly with length L (at const current density)**
 - For $\eta=85\%$, $Pr=3$, $G=550\text{cm}^{-1}$ (independent on length)
 - **2mm long chip: $R=0.03$, $\alpha = 1.6\text{cm}^{-1}$ and $\Gamma=2\%$**
 - **4mm long chip: $R=0.03$, $\alpha = 0.8\text{cm}^{-1}$ and $\Gamma=1\%$**
 - **8mm long chip: $R=0.03$, $\alpha = 0.4\text{cm}^{-1}$ and $\Gamma=0.5\%$**

– > **Need low loss and low confinement structures**

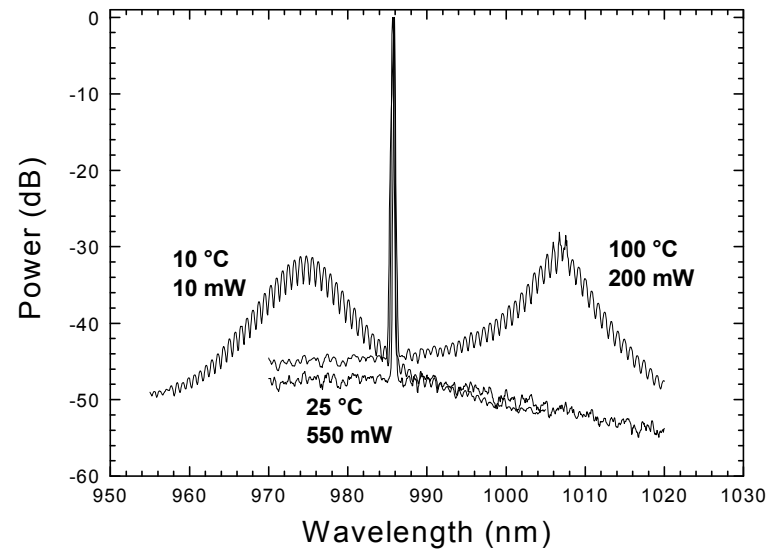
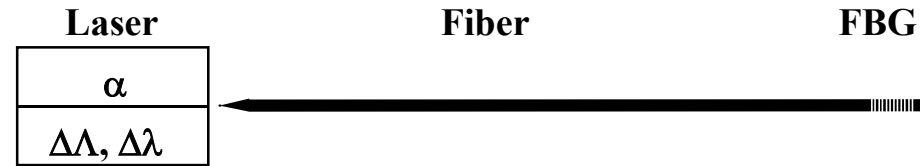
Wavelength stability



17nm Free Running Wavelength Shift
for 25mA - 500mA & 10°C - 40°C
=> **0.33nm/°C** and **0.015nm/mA**



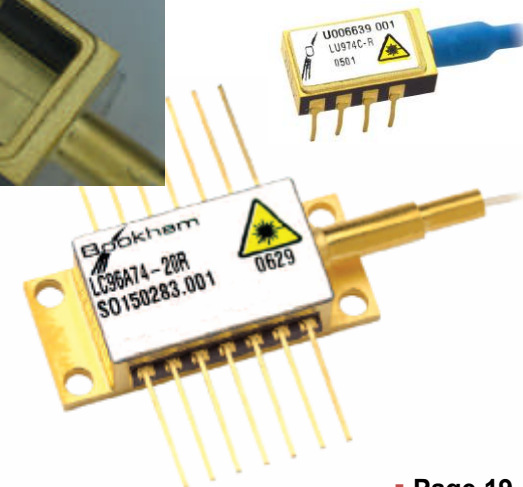
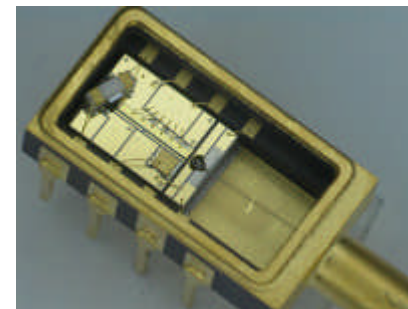
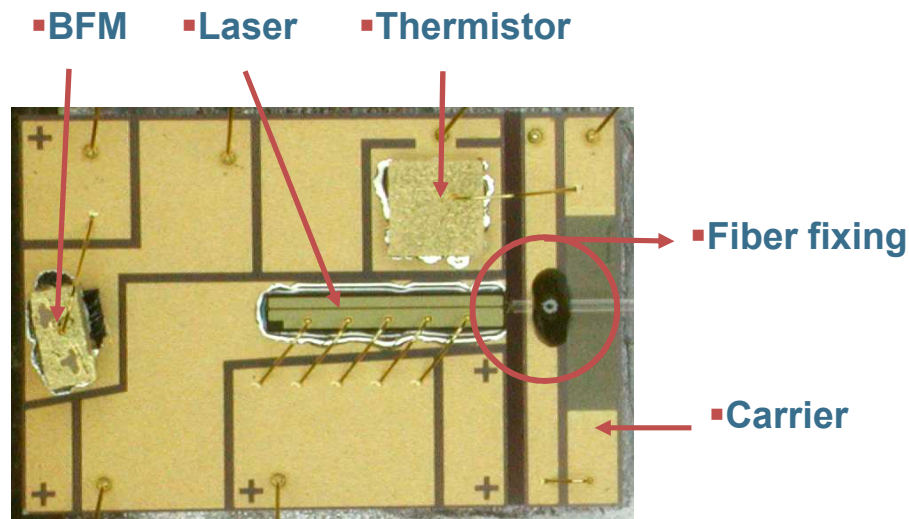
Wavelength Stability with FBG



- External fiber Bragg grating to lock wavelength

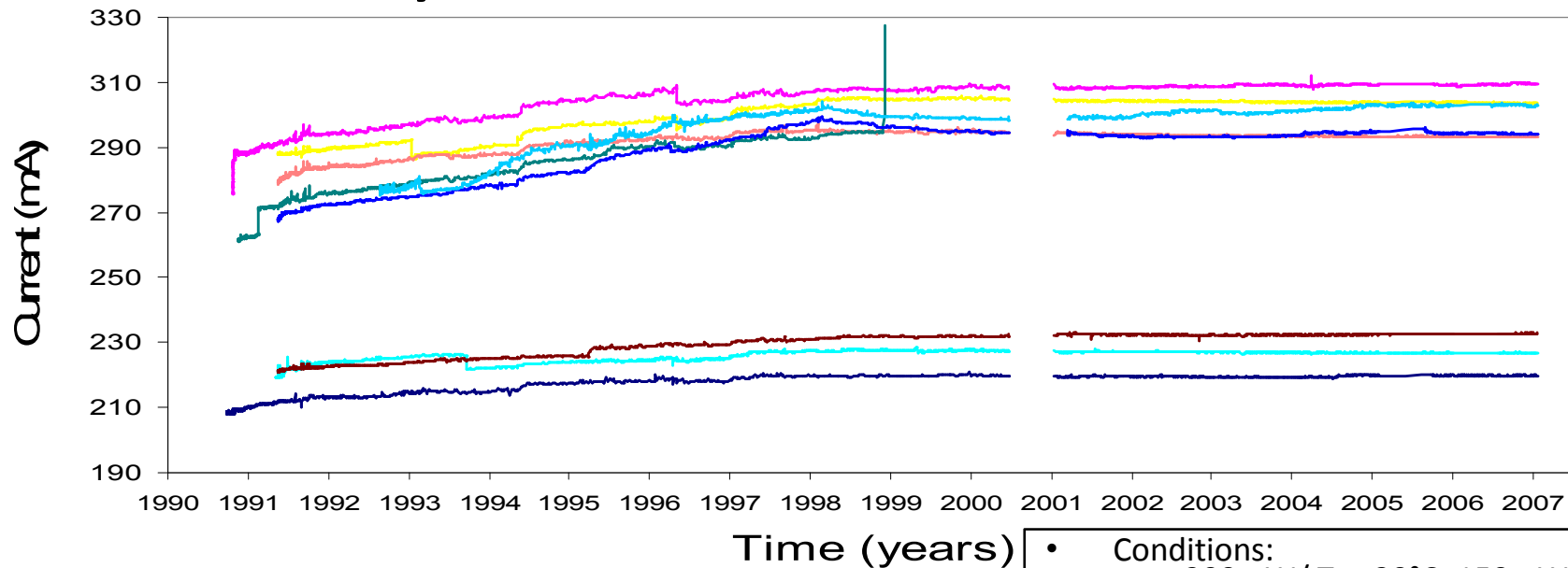
Single Mode Fiber Pump Module

- Fully monolithic planar AlN substrate
 - Extremely low mechanical creep
 - Cost effective automation
 - Excellent thermal properties
- Used in Butterfly packages and coolerless MiniDIL
 - i.e. 400 mW Submarine MiniDIL, 600mW Butterfly



Narrow Stripe

Reliability track record



Bookham Track Record

- First field deployment of 980nm pumps
 - 1993 (MCI from Chicago to Sacramento)
- Shipped from Zurich more than 1'000'000 devices into terrestrial deployments
 - Field reliability: <50FIT (0.05% return/year)
- 50'000 pumps in underwater transcontinental links
 - no fail of consequence
- Widespread
 - More than 50% of all optically amplified telecom and internet links worldwide are based on this technology (from Zurich directly or through licensed partners)
 -

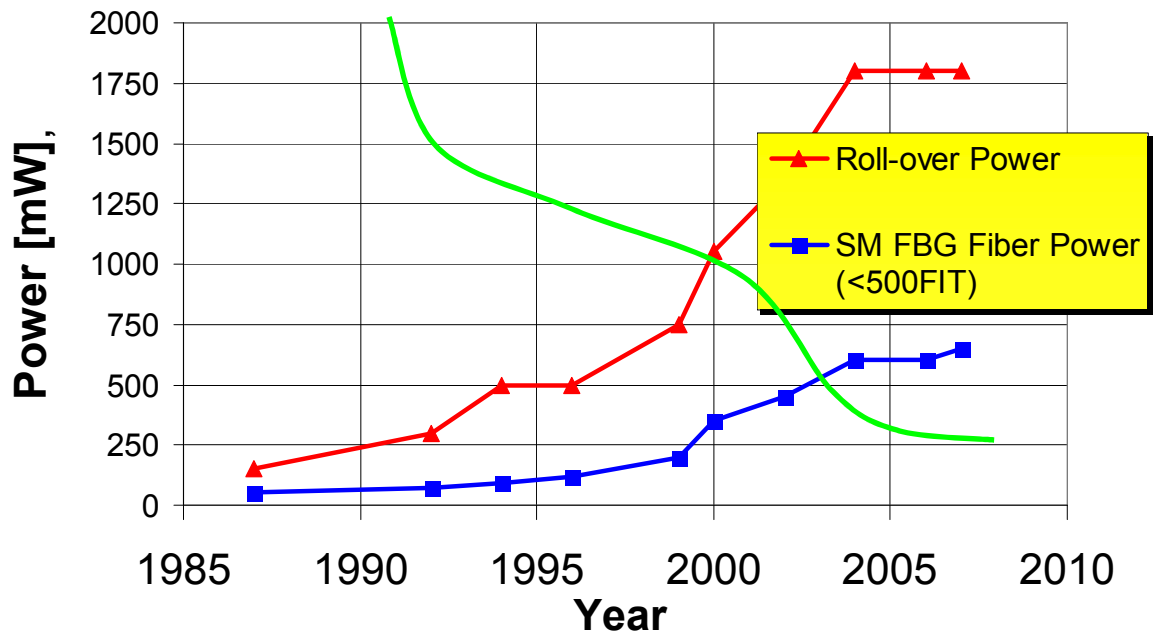
- Conditions:
 - 200mW/ $T_{hs}=30^{\circ}C$; 150mW/ $T_{hs}=75^{\circ}C$
- Reliability at 130mW/ $25^{\circ}C$:
 - Sudden Fail: 32 FIT
 - No wear-out

Courtesy Bookham

Narrow Stripe

980nm Single Mode Pump Diode:

Evolution of 980nm Single Mode Power



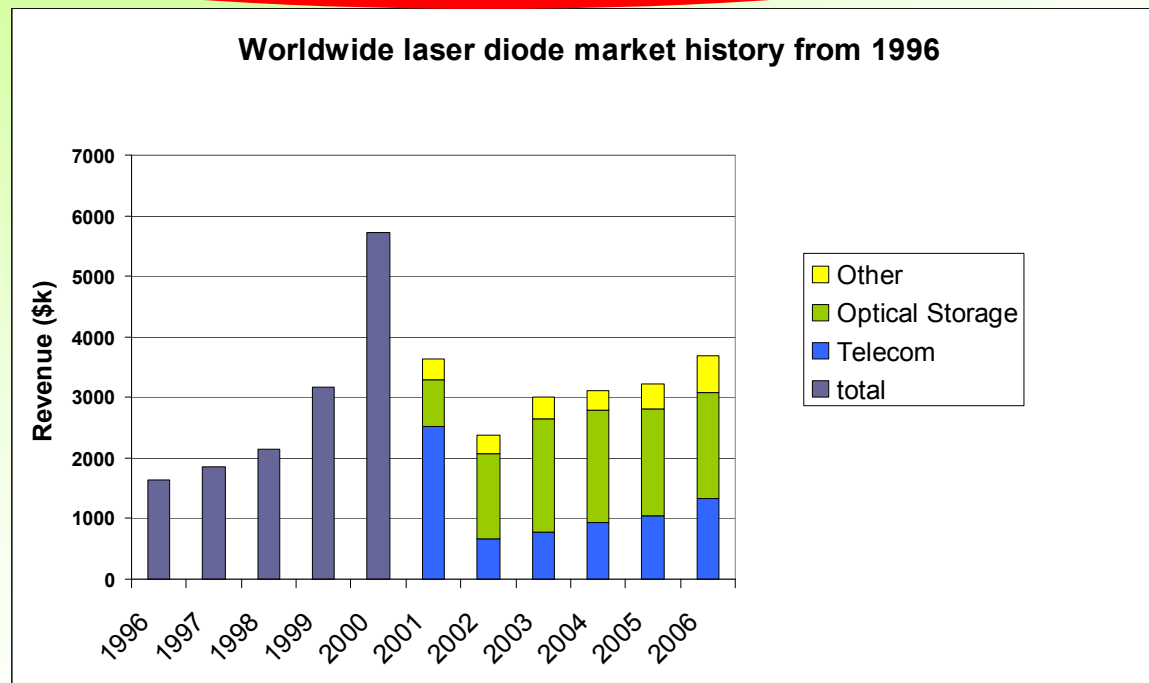
Price Reduction \$/mW
Factor of 10

980nm Pump Diode Lasers: Matured

- > Power has reached plateau at 700mW in Fiber
- > Cost to develop next length structure (lower waveguide loss and confinement) is too expensive for telecom market

Diode lasers will struggle to grow revenue

- Telecom experiencing margin erosion
- Optical storage squeezed out by flash



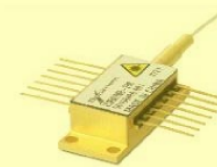
■ Sources: OIDA, OIDA members, Laser Focus, OIDA consultants

■ Michael Leiby
(leiby@oida.org)



■ Telecom and storage entering maturity?

SM Narrow Stripe Single Emitters

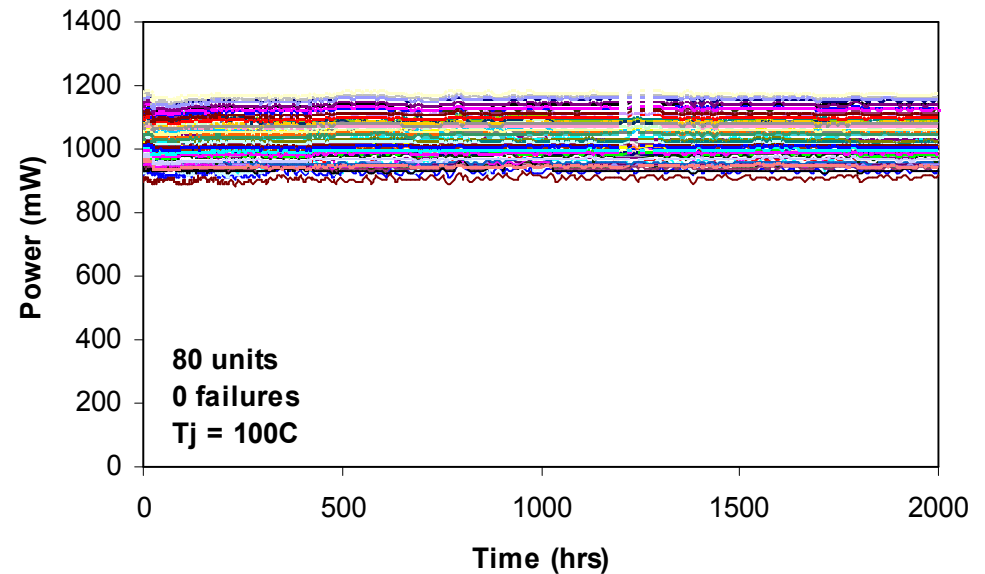
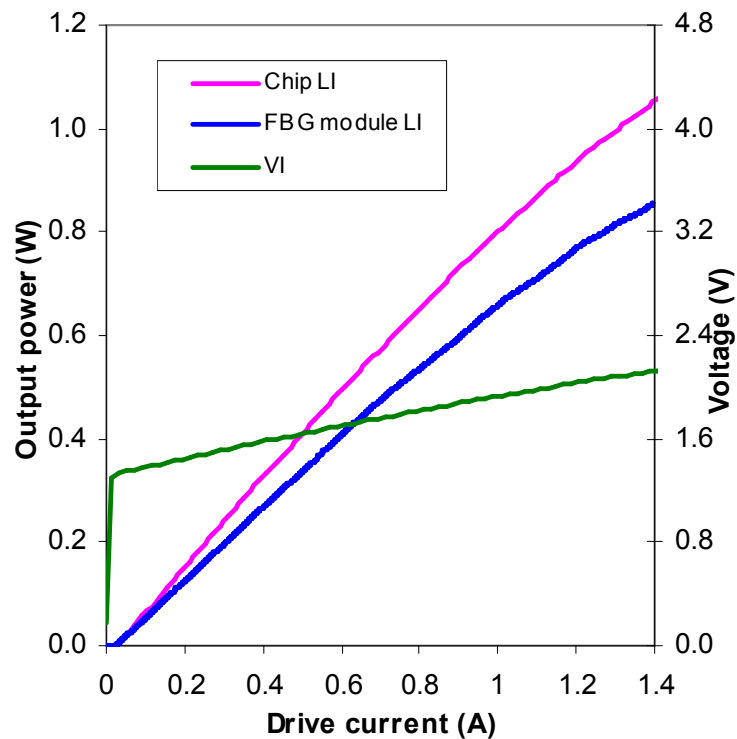
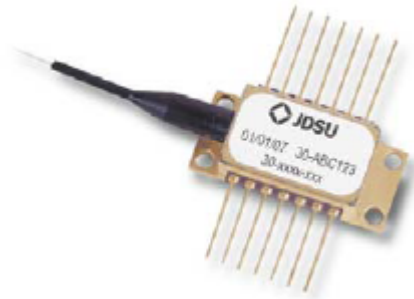


Chip Gen	980 Chip on Submount	980 Uncooled MiniDIL	980 Cooled BTF Package	976 SHG Pump BTF Package	10xx Laser BTF Package
G06	450mW		300mW		
G07	600mW	200mW	400mW	300mW	
G08	900mW		750mW		1.5-2A pulsed

- All wavelength stabilized
- <100FIT

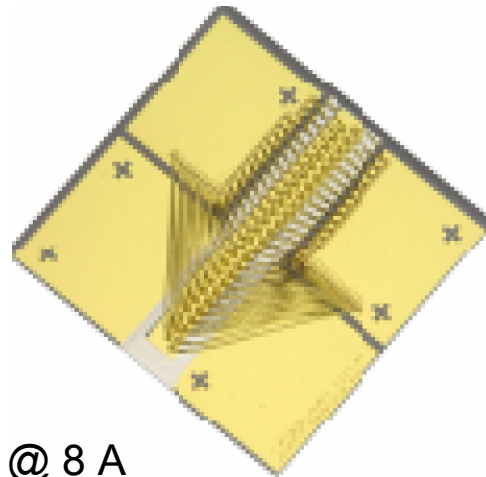
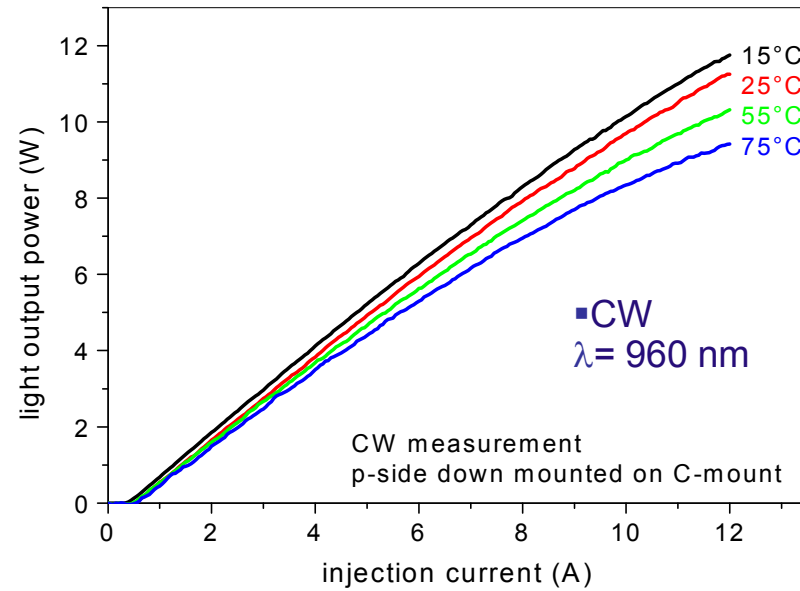
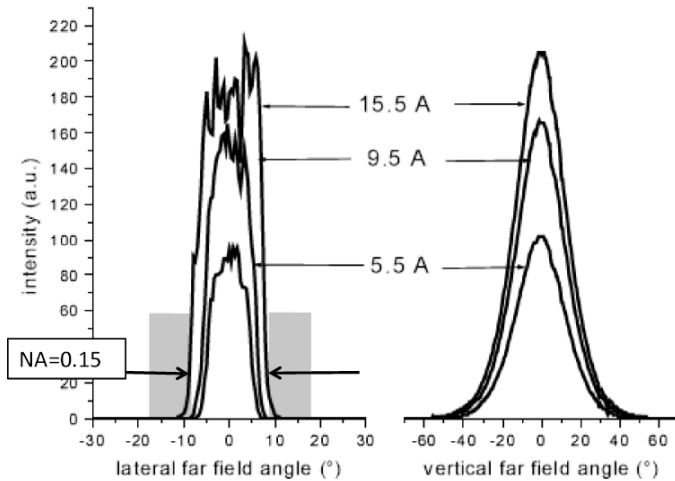
- Signal Lasers

JDSU 980nm Single Spatial Mode Pump

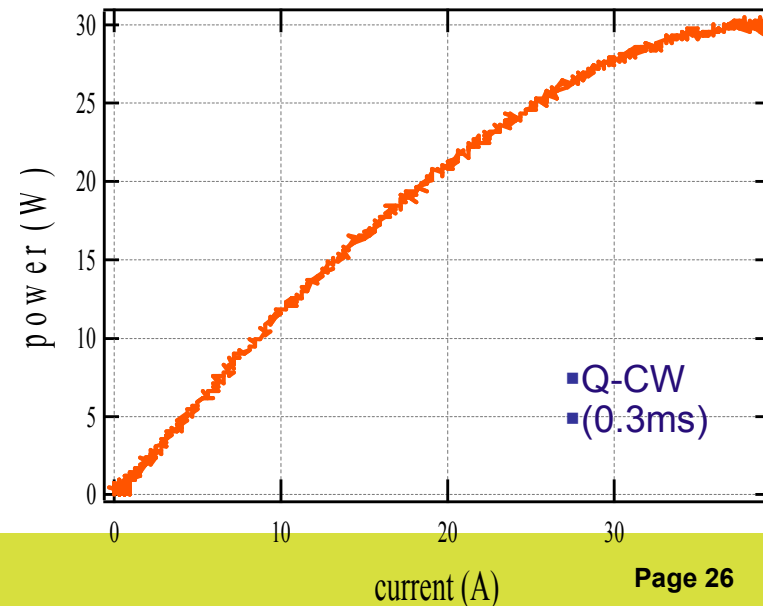


- New FBG-stabilized pump module
 - 660mW kink-free power
 - 45 FIT chip reliability at 830mW
- Mature package platform
 - 5 billion field hours
 - 5 FIT field reliability

SES8-9xx-01 performance



- Electro-Optical
 - Power: 8 W @ 8 A
 - Reliability: <5% fail in 10'000h



Broad Area Pump Diodes

Thermal Blooming at high Power



$$NA = n \sin \theta_{0,\max} = (n_1^2 - n_2^2)^{1/2} \approx (2 \cdot n \cdot dn)^{0.5}$$

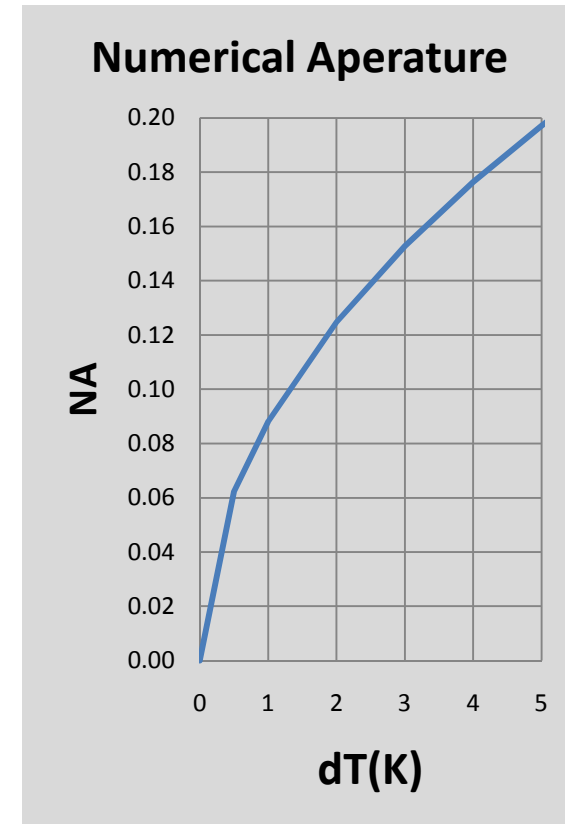
$$dn = dn/dT \cdot dT$$

NA=0.1 > dT<1.5K !!

$$dn/dT = 3 \cdot 10^{-4}, n = 3.6$$

Avoid temperature rise in active stripe

- > High power conversion efficiency
- > Long cavities
- > Good heatsinking



Broad Area Pump Diodes

History to reduce NA

Designidea: Reduce thermally broadended NA by

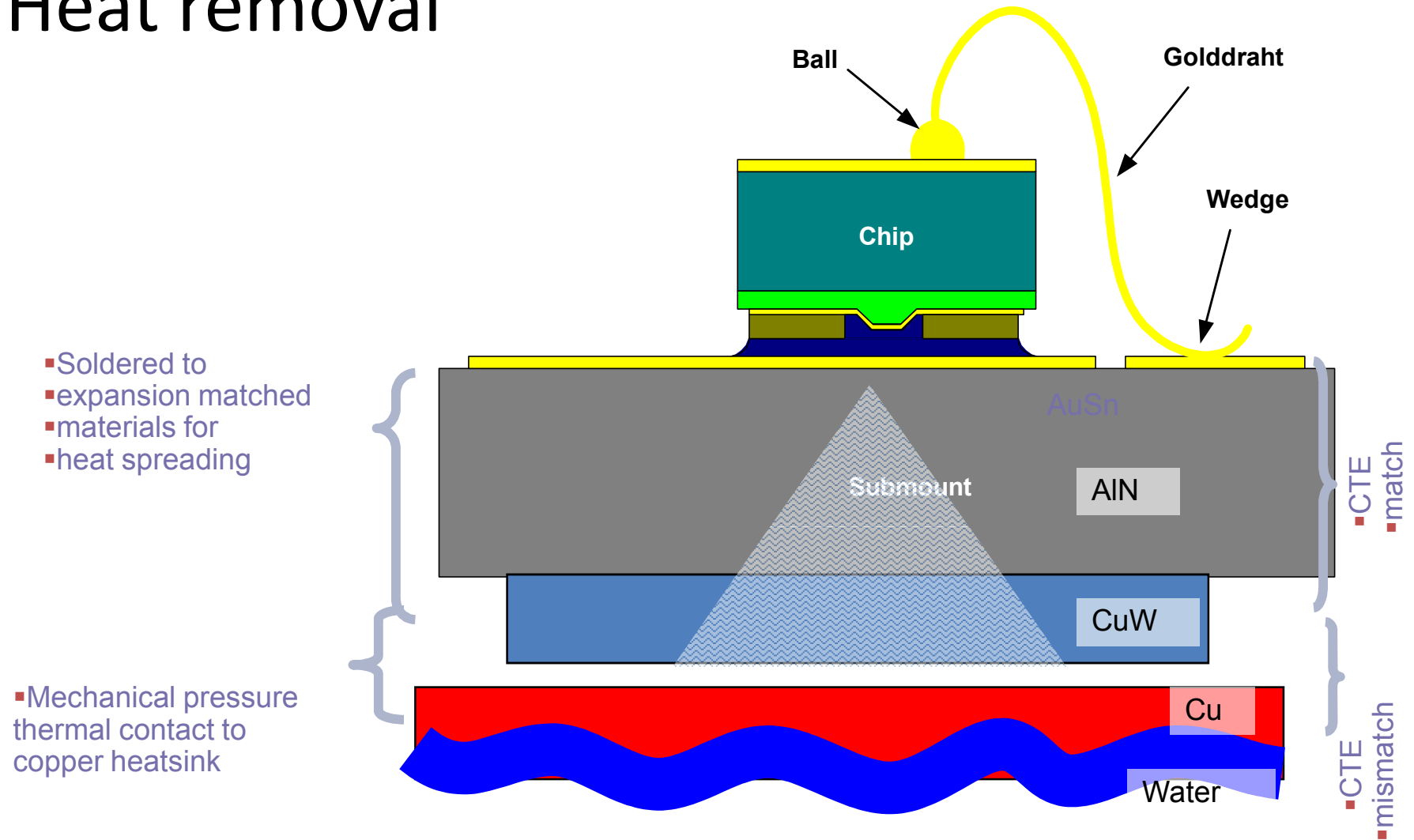
1. Coherent arrays
2. Surface grating lasers
3. MOPA
4. Taper Laser
5. Alpha DFB
6. Large Area VCSEL

None of these designs was successful.
Too difficult to manufacture
Reliability (beam stability) issues

Today, simple single stripe broad area are mostly used with good thermal control

9xxnm Multimode Pump Diodes

Heat removal



9xx MM Broad Area Single Emitters



WL	Chip on Submount	Chip on C-Mount	Uncooled Module 2-pin	Multi-Emitter Module 2-pin
915, 940, 960, 975nm	9W SES9-9xx-01	9W SEC9-9xx-01	8W BMU8-9xx-01/2-R	20W MU20-9xx-01/2-R
915, 940, 960, 975nm	11W SES1 1-9xx-01	11W SEC1 1-9xx-01	10W BMU10A-9xx-01/2-R	

- Chip stripe width: 90um
- AlN submount or Cu C-mount
- Passively cooled packages with floating anode/cathode
- 105um fiber with 0.22/0.15NA

20W Multi-Emitter Module



- **Module**

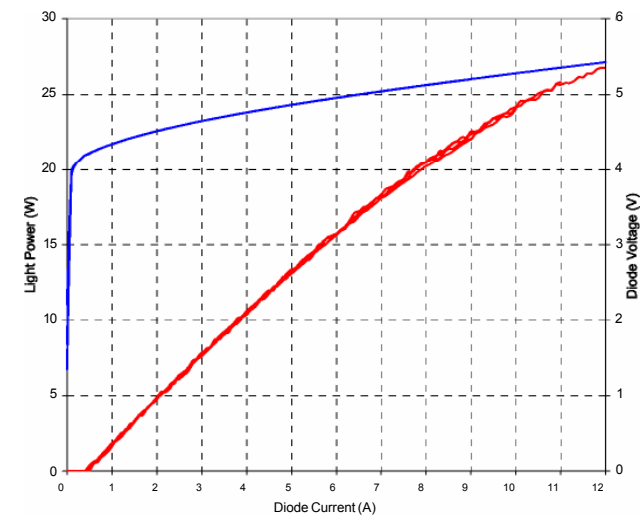
- 3 single emitters inside
- 2-pin package
- 0.15NA or 0.22NA in 105um fiber
- Floating anode/cathode
- 1060nm blocking filter included



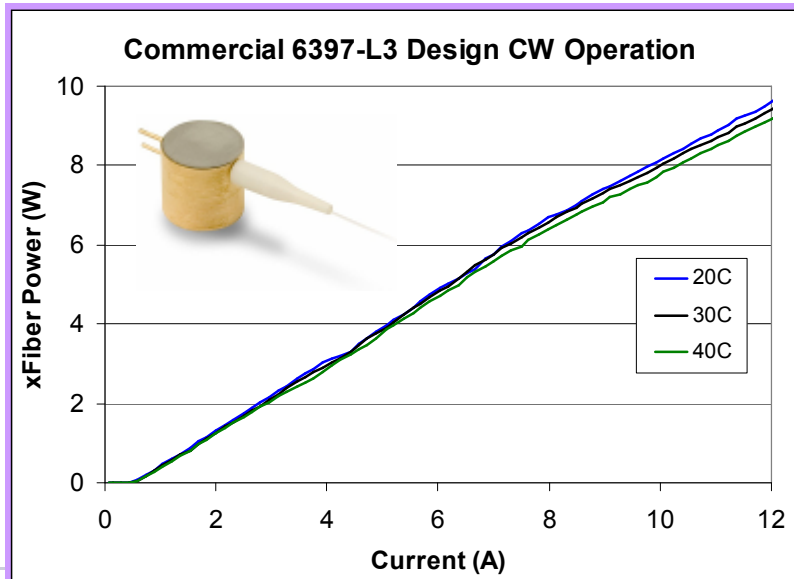
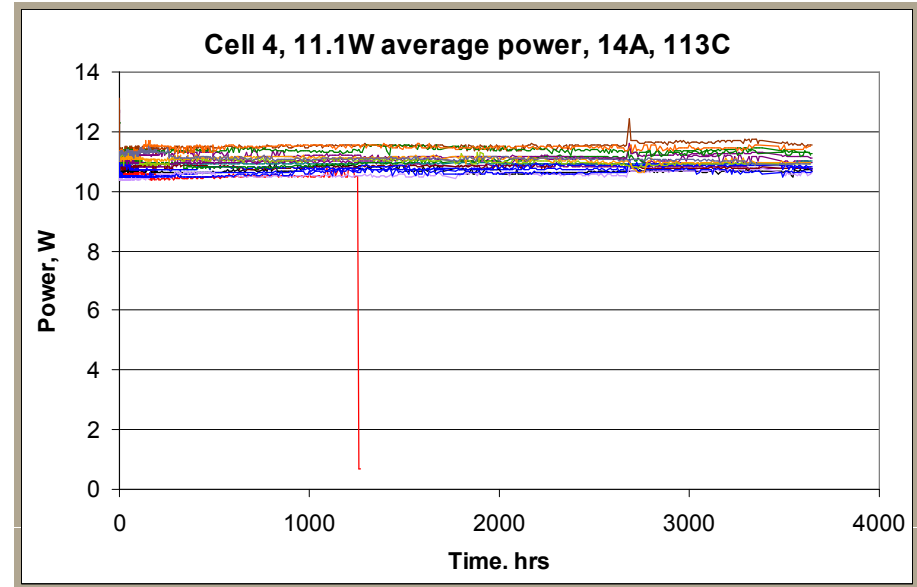
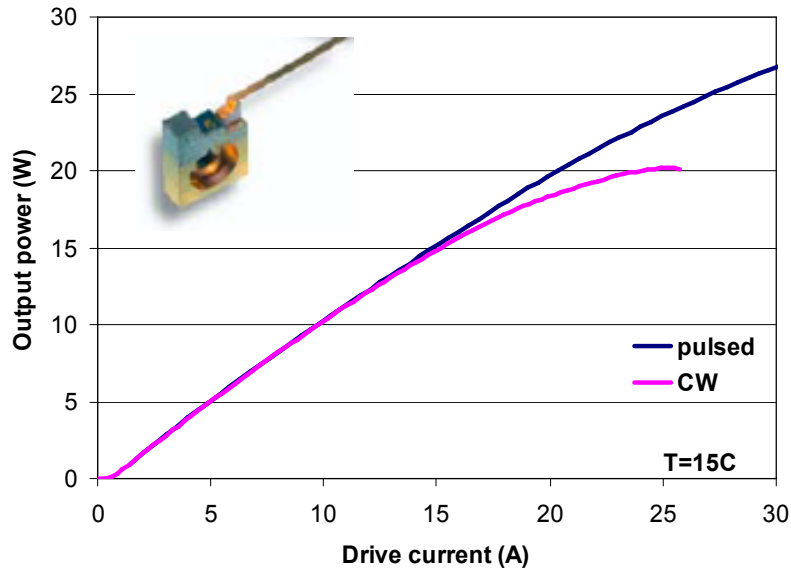
- **Electro-Optical**

- Power: 20W
- Current: <9A
- Wavelengths: 915, 940, 960, 975nm

P-I -V Curves of 0.15NA 20W Modules:



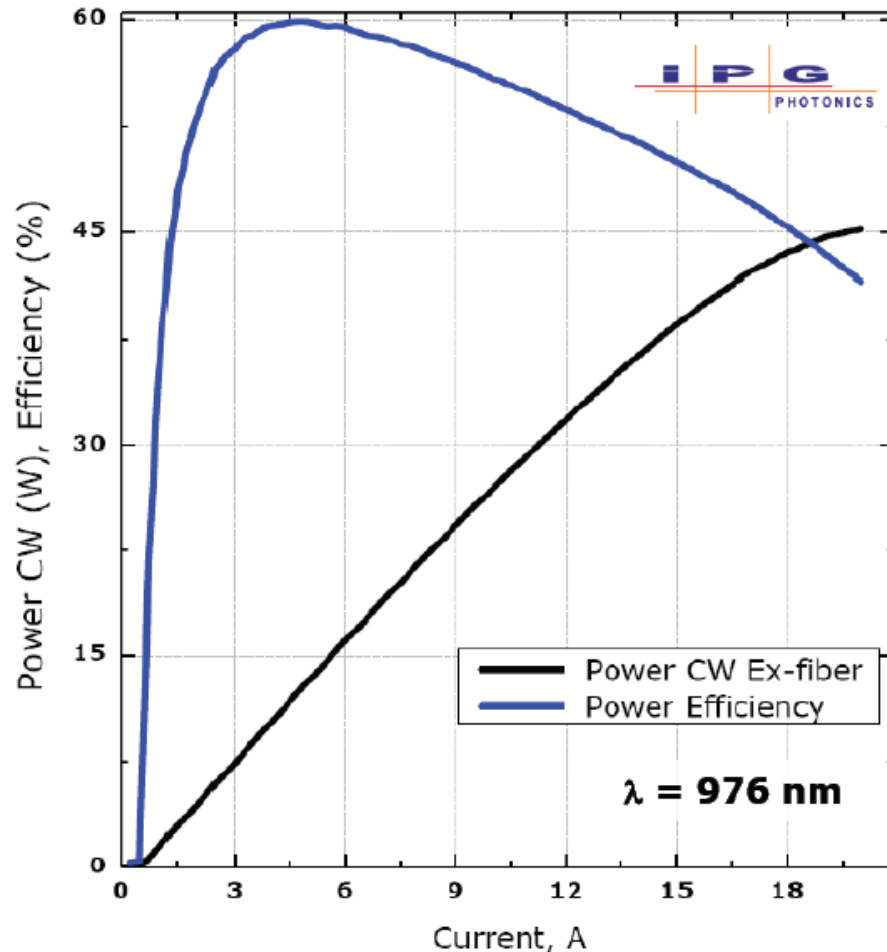
JDSU 9XXnm Multi Mode Pump



- 100 μ m wide aperture chip
 - 20W CW rollover power
- 105 μ m diameter, 0.2NA fiber
 - 8W rated power at 10A

Example IV: Fiber Coupled Devices of 2008 design:

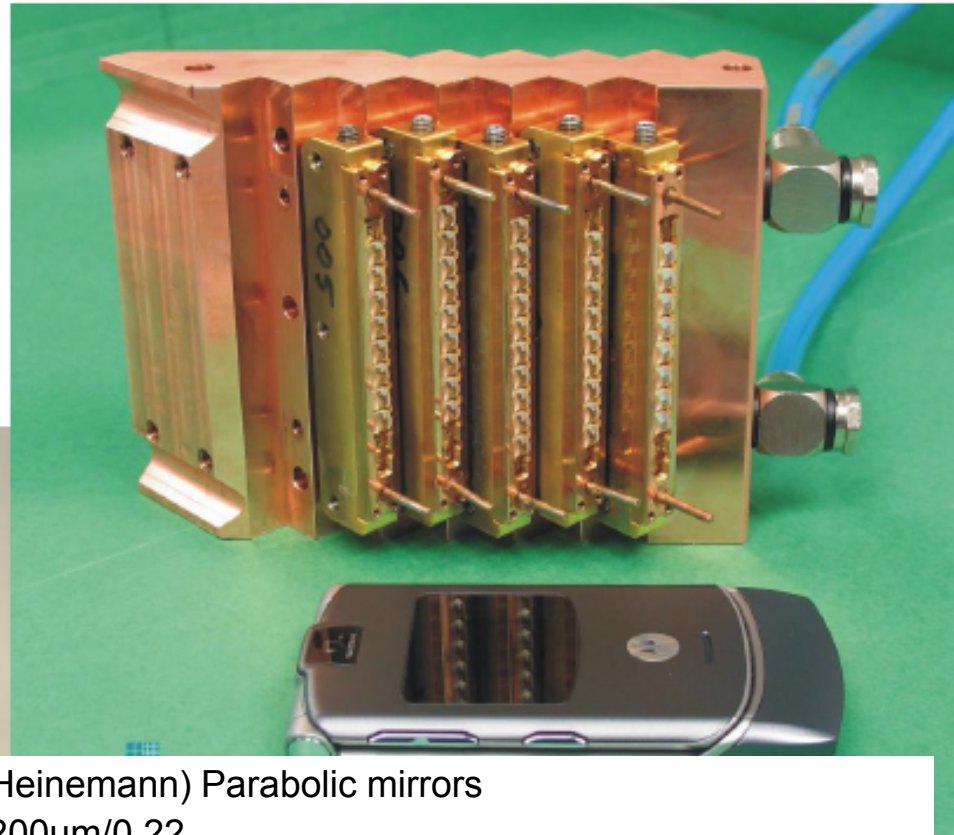
PLD-30-9xx series (based on L=4.5mm COS): $\varnothing=100\ \mu\text{m}$ fiber , $\text{NA} < 0.12$



- Single emitter-based technology ensures high reliability of the pumps
- High fiber coupling efficiency (>90%) ensures industry highest power, brightness and power efficiency



2D Single Emitter Arrays for Ultra High Brightness Diode Laser



- Fraunhofer (Heinemann) Parabolic mirrors
 - 500W 200um/0.22
 - Alignment (lens <math>< 50\text{nm}</math>, PA FA/SA 0.1mrad, lens 0.05mrad).

Fraunhofer USA


Center for
Laser Technology


smart laser tools

Power Photonics

Fused and Proximity Combiner

Fused: $(6+1)*1$

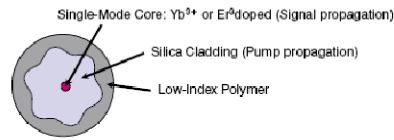


Figure 2 Cross-section of double-clad optical fiber for cladding pumping.

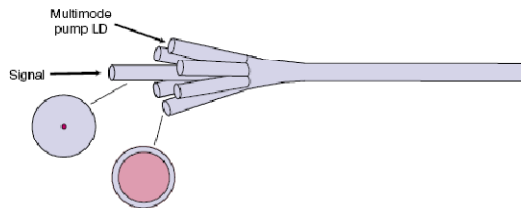
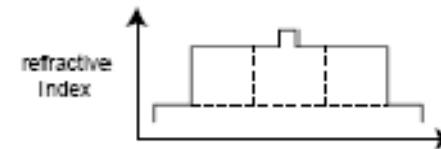
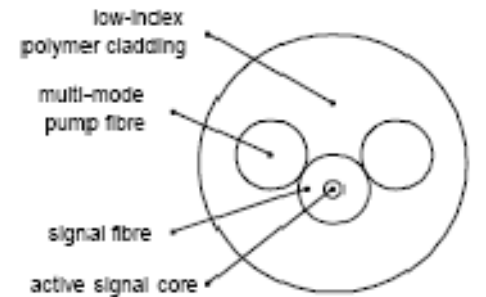


Figure 3 Schematic of tapered fiber bundle.

	Fiber	NA
Signal input	HI 1060	
Pump Ports	6*105um	0.22
Output	20um/400um	0.06/0.46

Proximity: $(2+1)*1$

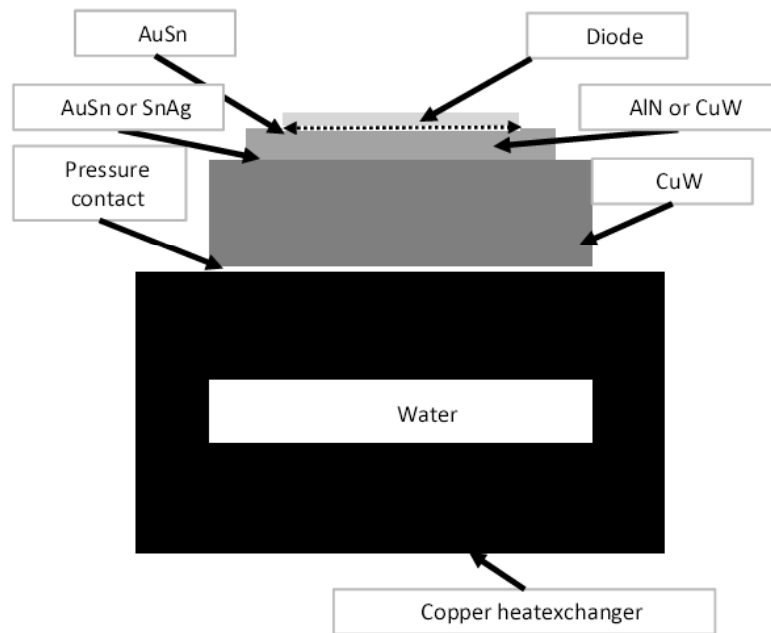


- Fused can be extended to beyond 20 inputs
- Proximity needs high brightness pumps

Broad Area laser Diodes

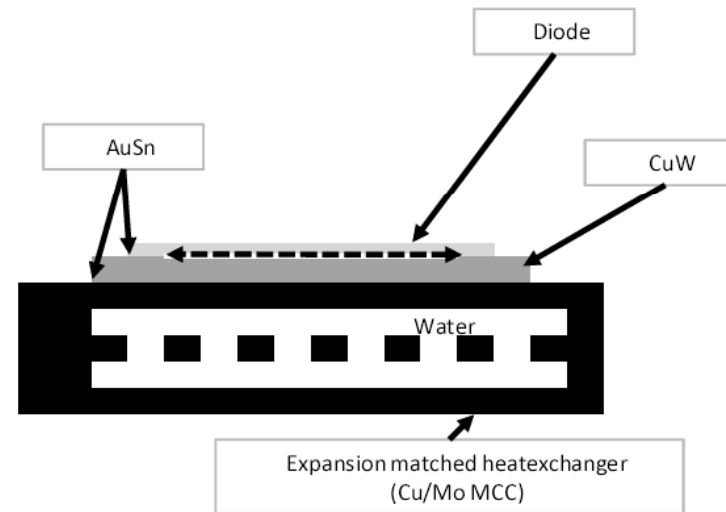
Single Stripe and Bar Wide

Passive Cooling



Cooling by heat spreading
Clamped to heatexchanger

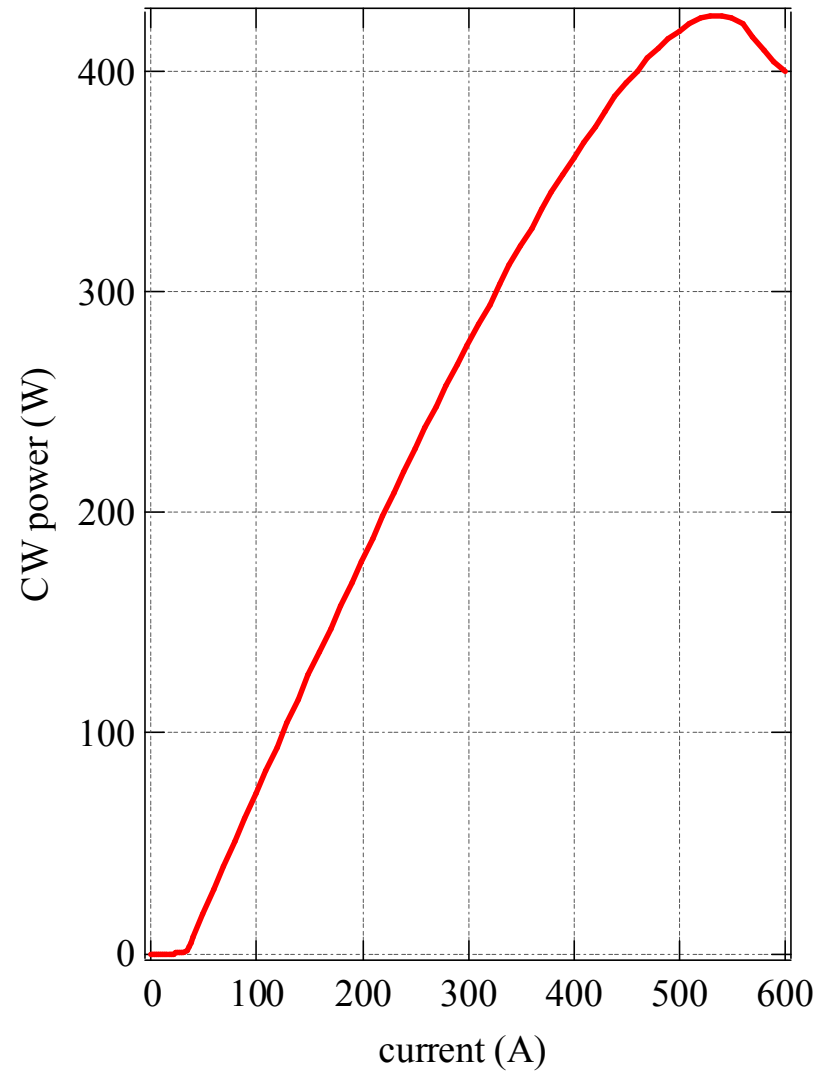
Active Cooling



Cooling by Mico-Channel Cooler
All AuSn soldered



- 425W at 980nm, 1cm, 50% FF
- On standard MCC
- 3.6mm long laser cavity



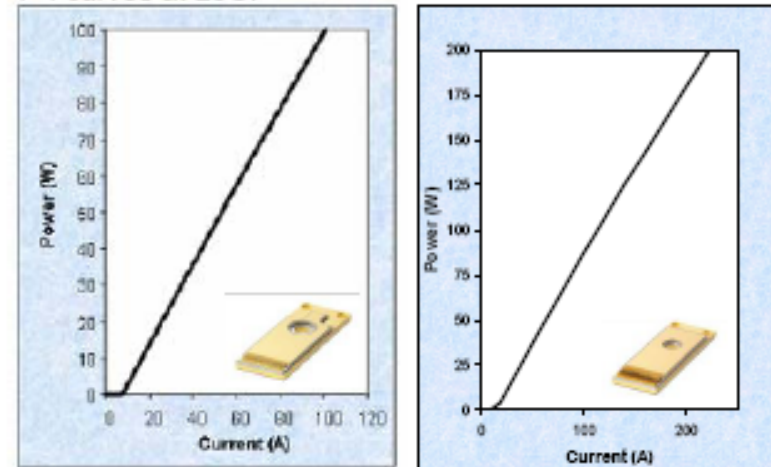
9xxnm 50%FF BAC Performance



- **Electro-Optical**

- Power	80W	120W
- Drive Current:	87A	140A
- Threshold:	9A	14A
- Slope Eff.:	1W/A	1W/A
- Efficiency:	60%	60%
- LFF (90%PC):	7°	7°

P-I curves at 25C:

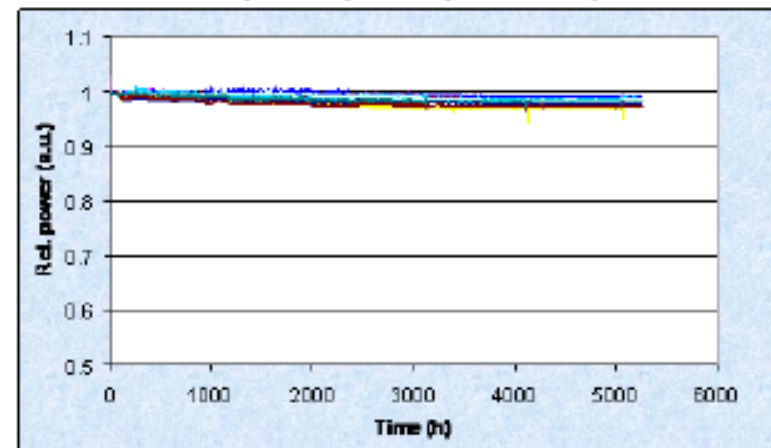


- **Reliability**

⇒ MTTF >20'000hrs or >100 MCycles
(in accordance with ISO17526:2003)

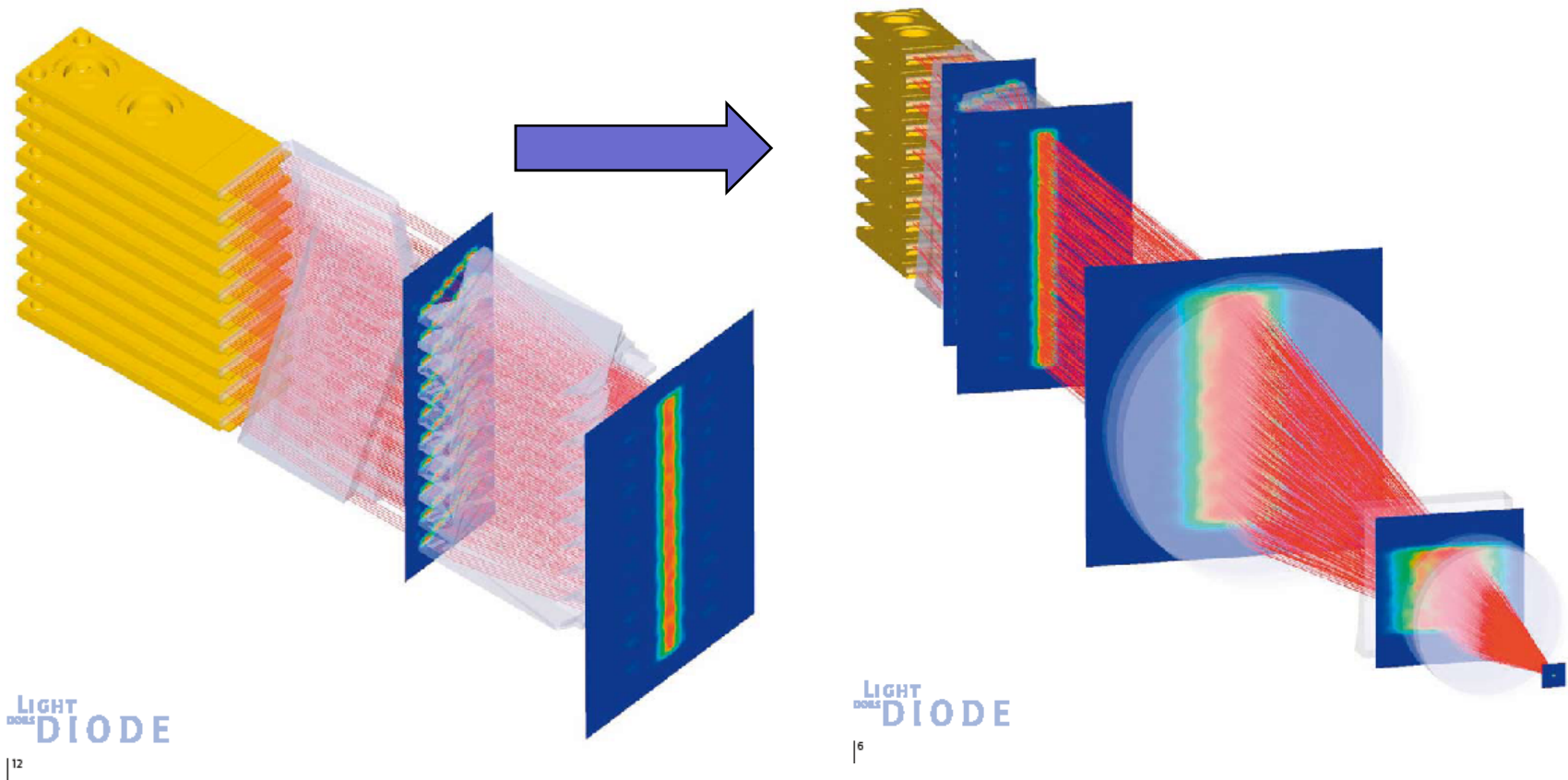
⇒ Data available suggests for the
semiconductor 80'000hrs or 350 MCycles
(less than 1% fails after 120 MShots)

Lifetest at 120W pulsed (1.33Hz, 0<->140A)



intense

Bar multiplexing to achieve highest optical power densities for direct application



Direct Coupled Diodes:

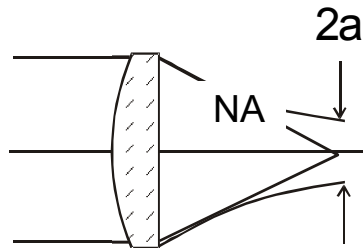
Products: Fiber-coupled Diode Laser



- Laser power: 90 - 6.000 W
- Fiber diameter:
 - 200 μm 80 – 200 W
 - 400 μm 90 – 850 W
 - 600 μm 150 – 1.300 W
 - 1.000 μm 300 – 4.000 W
 - 1.500 μm 3.000 – 6.000 W
- NA 0,2
- In total 36 different lasers available

Laserline GmbH, Germany

Beamquality



Beam with aperture radius of “a” and divergence of “NA”

The beam parameter product is

- $BPP = a \cdot NA$

The etendue (throughput) is

- $Etendue = (a \cdot NA \cdot \pi)^2$

- or $a \cdot b \cdot NA_x \cdot NA_y \cdot \pi^2$ for an elliptical beam

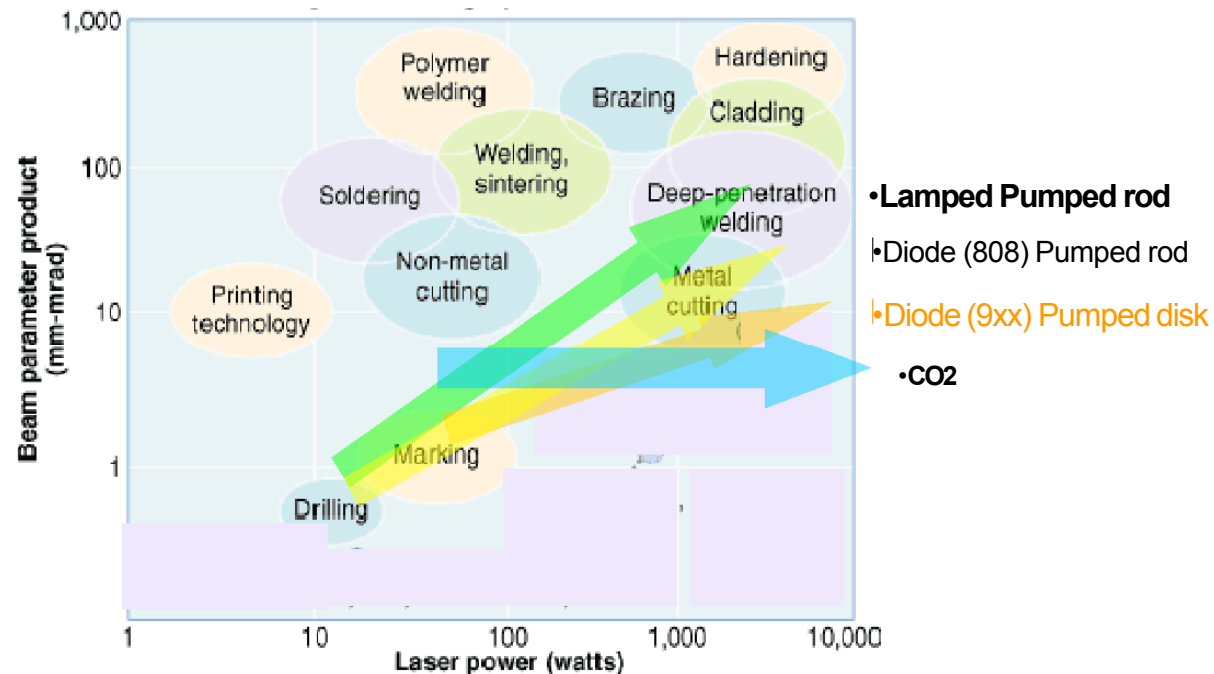
The minimum beam parameter product and etendue (corresponding to a single lateral mode) is given by

- $BPP = a \cdot NA = \lambda / p = 0.32 \mu m \cdot rad$ for $\lambda = 1 \mu m$

- $Etendue = (a \cdot NA \cdot \pi)^2 = \lambda^2 = 1 \cdot 10^{-8} \text{ cm}^2 \text{ ster}$ for $\lambda = 1 \mu m$

A single mode 1 Watt laser yields $100 \text{ MW} / (\text{cm}^2 \text{ ster})$

•Klassische Laser Strahlwerkzeuge



- Hybrid Laser Systems
 - Hybrid systems (Diodes, Lamps, Crystals, Dielectric Mirrors), Non hermetic cavity, Free space propagation
 - Beam limited by heat in active material
- Applications
 - Academia: Ideal for manipulation of beam
 - Industry: Delicate operation

Coupling Laser Diodes to a Fiber

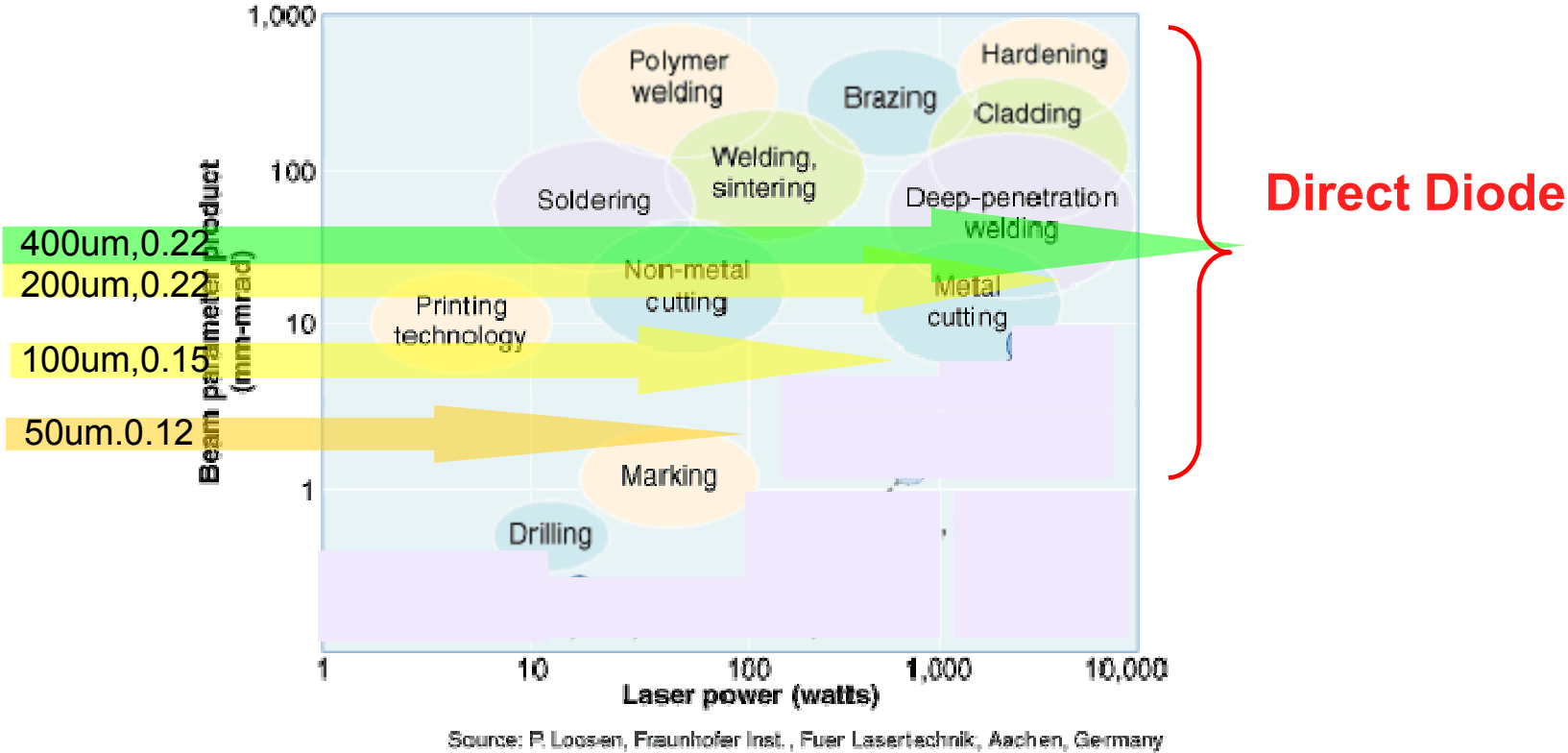
Diode Laser	Beam Width [μm]	NA [rad]	Fast axis BPP [$\mu\text{m rad}$]	Slow axis BPP [$\mu\text{m rad}$]	Etendue [$\mu\text{m}^2 \text{sr}$]
Single mode diode	5	0.12	0.3	0.3	1
Standard BA diode at low power	100	0.05	0.3	3	8
Standard BA diode	100	0.09	0.3	5	14
Low NA wide BA diode	200	0.09	0.3	9	28
Low NA minibar	3'200	0.07	0.3	112	340
Fiber	Core Diameter [μm]	NA [rad]	BPP [$\mu\text{m rad}$]		Etendue [$\mu\text{m}^2 \text{sr}$]
SM fiber	5	0.12	0.3		1
Input fiber for fiber combiners	105	0.15	8		610
Standard material processing delivery	200	0.22	22		4'800
High power material processing delivery	400	0.22	44		19'000
Fiber of cladding pumped laser	400	0.46	92		84'000
High power material processing delivery	1'500	0.46	345		1'200'000

Theoretical limits:

- 4800 single mode lasers fit in a 200 μm /0.22NA fiber
- 350 Standard BA lasers fit in a 200 μm /0.22NA fiber

With polarization multiplexing and wavelength division multiplexing even more diodes can fit in the fiber

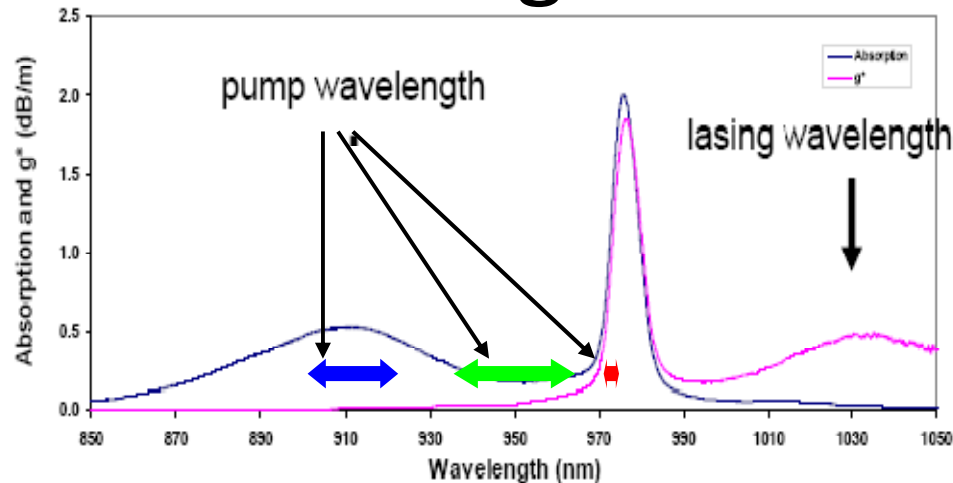
Direct Diode Capability:



- Base of Arrow: Commercial, single wavelength, single polarization.
- Tip of Arrow: limit with single wavelength, single polarization (1W/mode)

Power Photonics

Yb fiber wavelength: 9xx bands



Yb: Glass fiber absorption and emission spectrum

Wide pump band: 870nm to 980nm

Blue band (915nm): Good absorption, wideband

- Preferred for lower power, high gain stage

Green band (940nm..960nm): Lowest absorption, wideband, high optical conversion

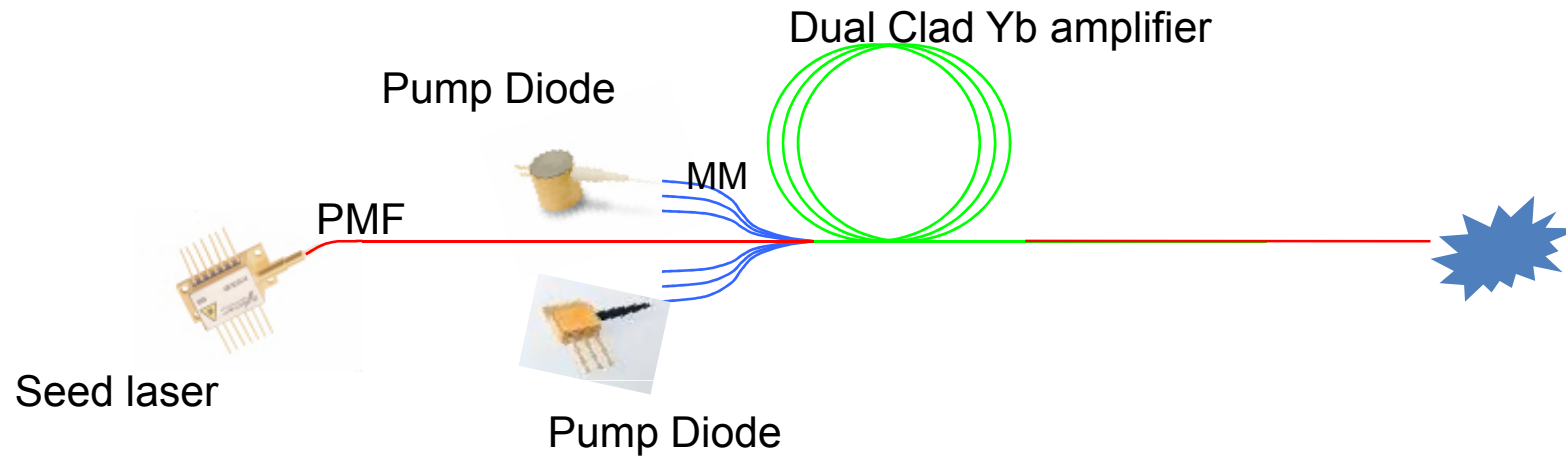
- Preferred for very high power stage

Red band (976nm): Highest absorption, narrow width

- Preferred for high gain amplifiers and q-switched lasers with short fiber (SBS)
- **Pump diode challenge: Diode wavelength control (+/-2nm) necessary**

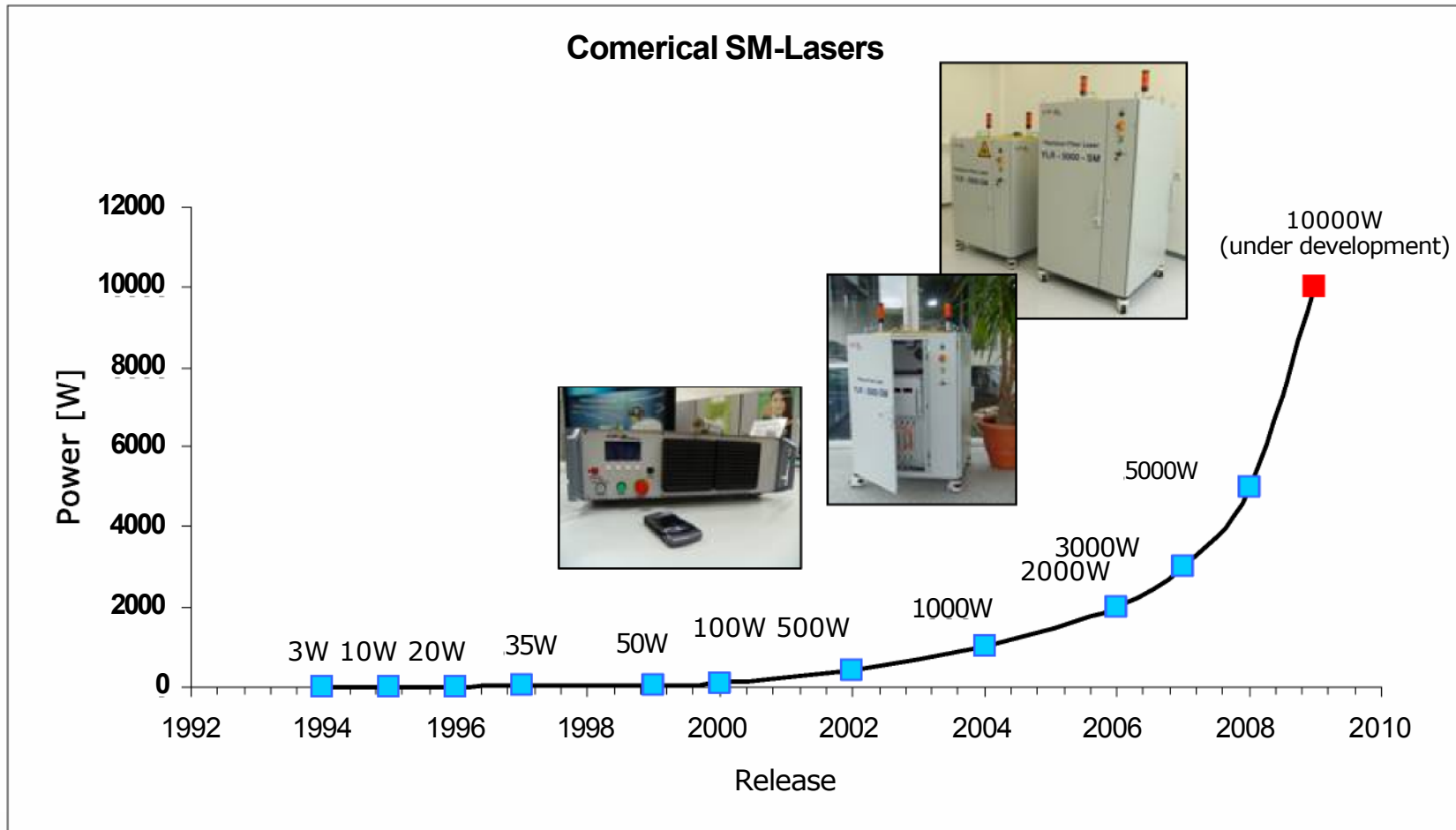
Power Photonics

Fiber “Laser” = Fiber MOPA



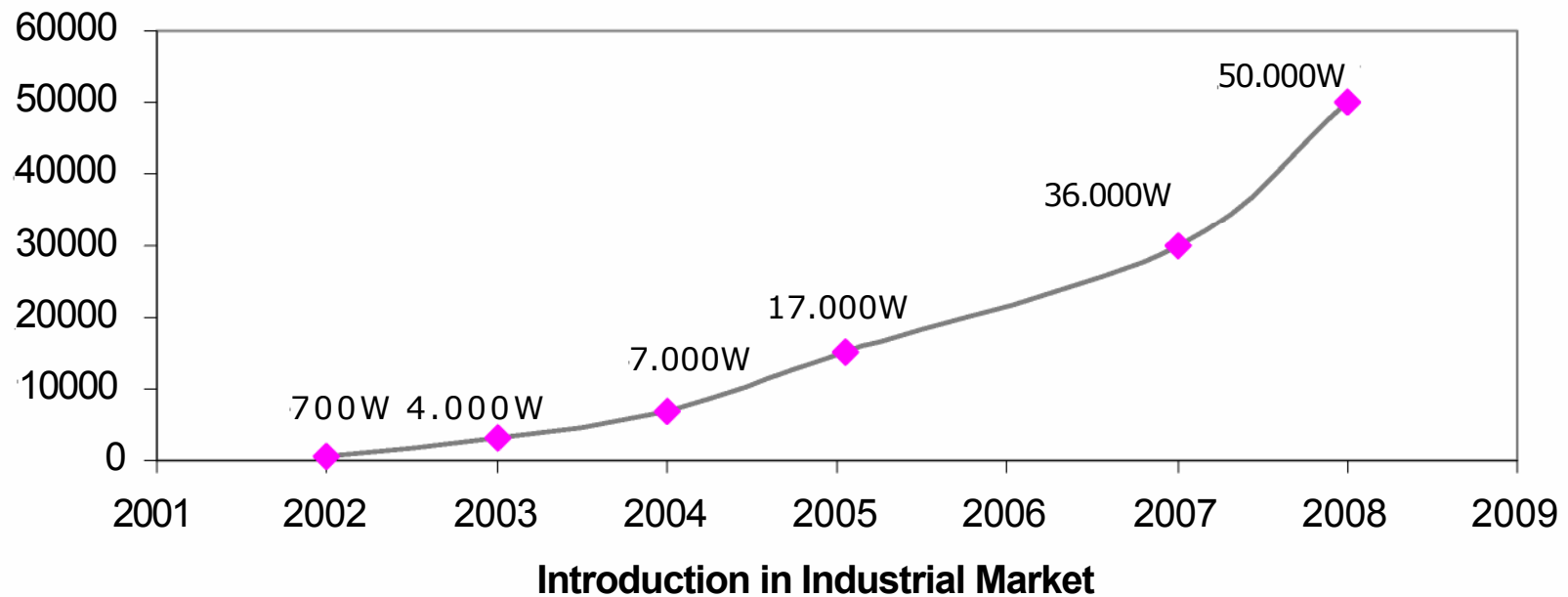
- Seed laser
 - Fiber laser: Good spectral control
 - Need external modulators (Pockels Cell)
 - Diode laser: Excellent dynamic control
 - FP laser have poor spectral control, of no concern
 - DFB have excellent spectral and dynamic control
- Pump laser
 - Single emitter broad area MM diode

Status and Development of Single Mode Fiber Lasers

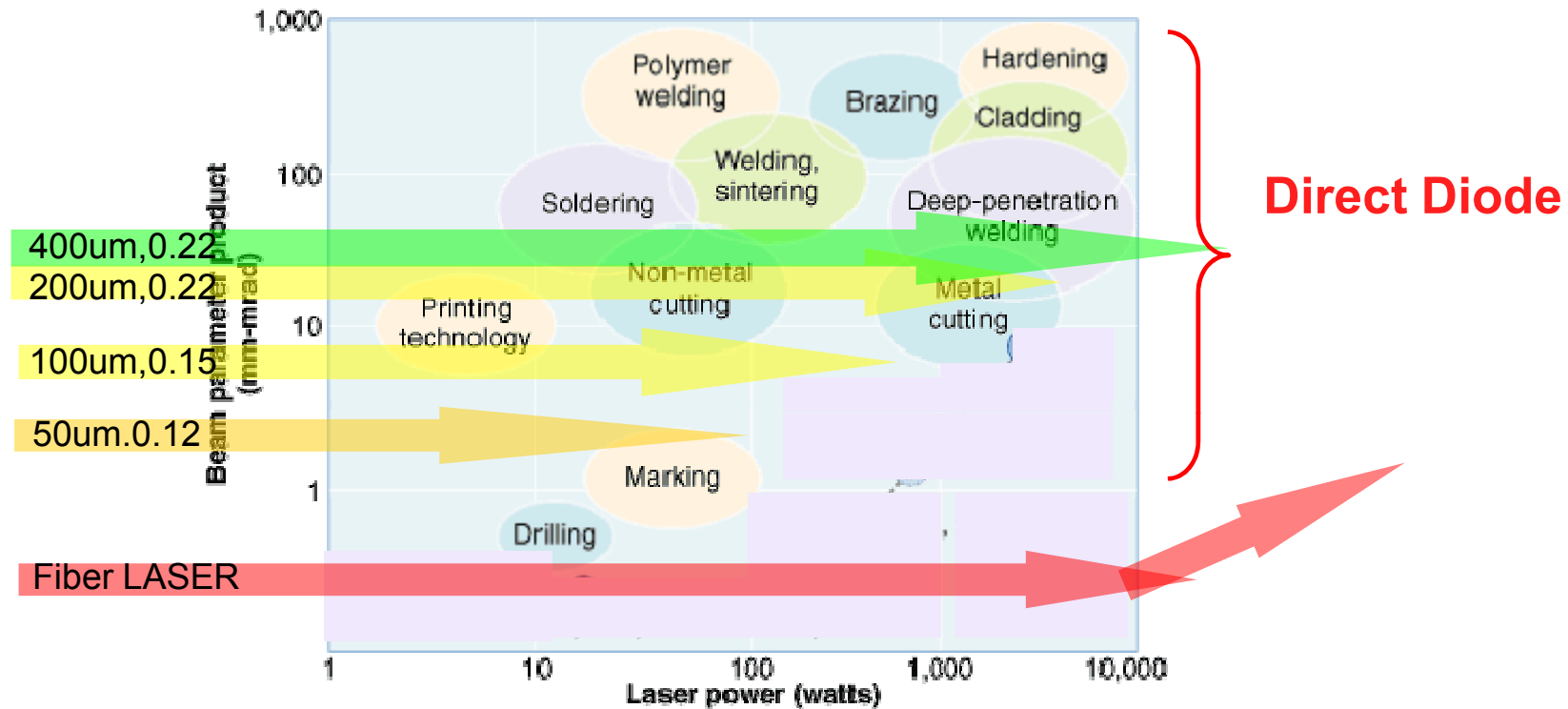


High Power Fiber Lasers - History

Power development of Low Order Mode Fiber Lasers



Direct Diode Capability:



Source: P. Loosen, Fraunhofer Inst., Fuer Lasertechnik, Aachen, Germany

Reduce Cost of coupling diodes to the fiber

Base of Arrow: Commercial, single wavelength, single polarization. Tip of Arrow: limit

intense

Application example: welding of thin foils

Foils

-Polypropylen (PP)
transparent and black
thickness 100 μm

Microfluidic device

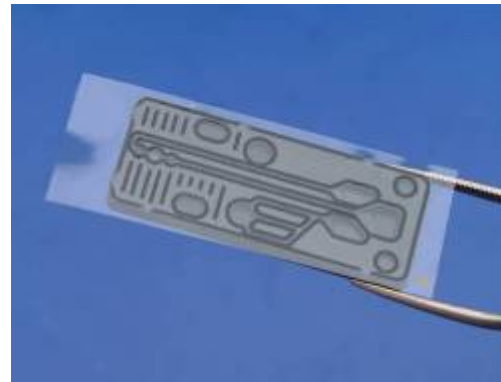
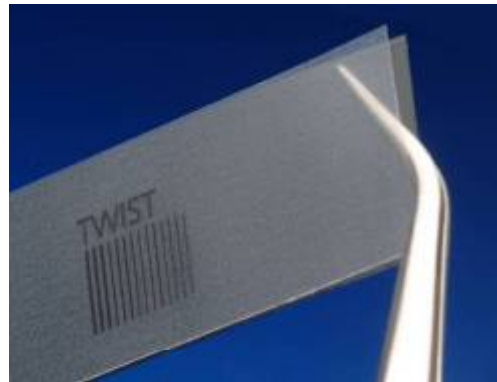
- PMMA or PP sealing
foil (75 μm)

$P = 1,4 - 5,9 \text{ W}$

$v = 50 \text{ to } 250 \text{ mm/s}$

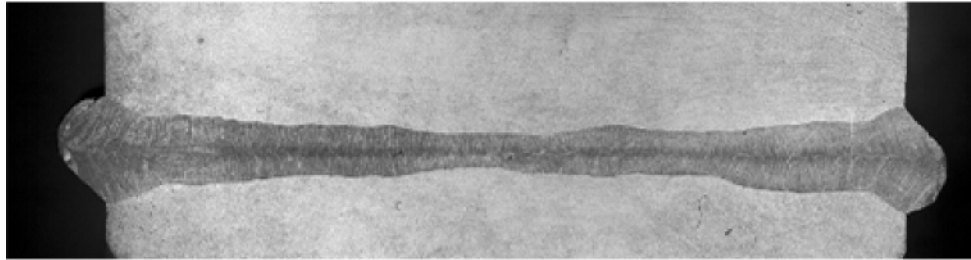
$d_0 = 70 \mu\text{m}$

$d_{\text{weld seam}} = 150 \text{ to } 500 \mu\text{m}$

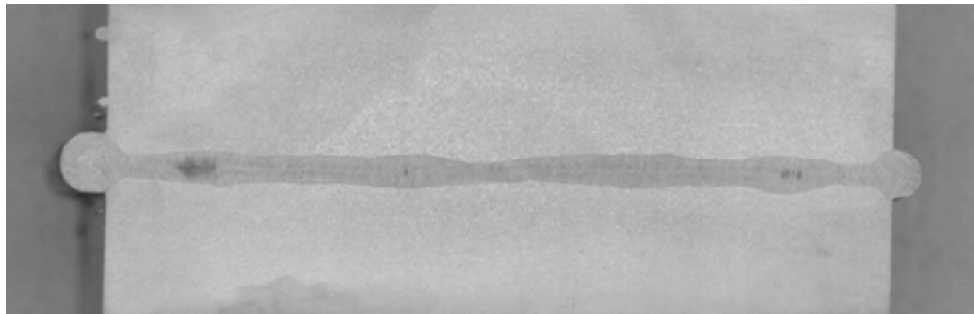




Double sided butt joint 30kW



2" stainless steel



$P=30 \text{ kW}$, $v= 2,0 \text{ m/min}$





Single Mode Welding



Power: 3kW

Stainless Steel

$v=0.5\text{m/min}$

Depth=1.3mm

Width \approx 1mm

$v=10\text{m/min}$

Depth=6mm

Width \approx 0.2mm !!!



Source:



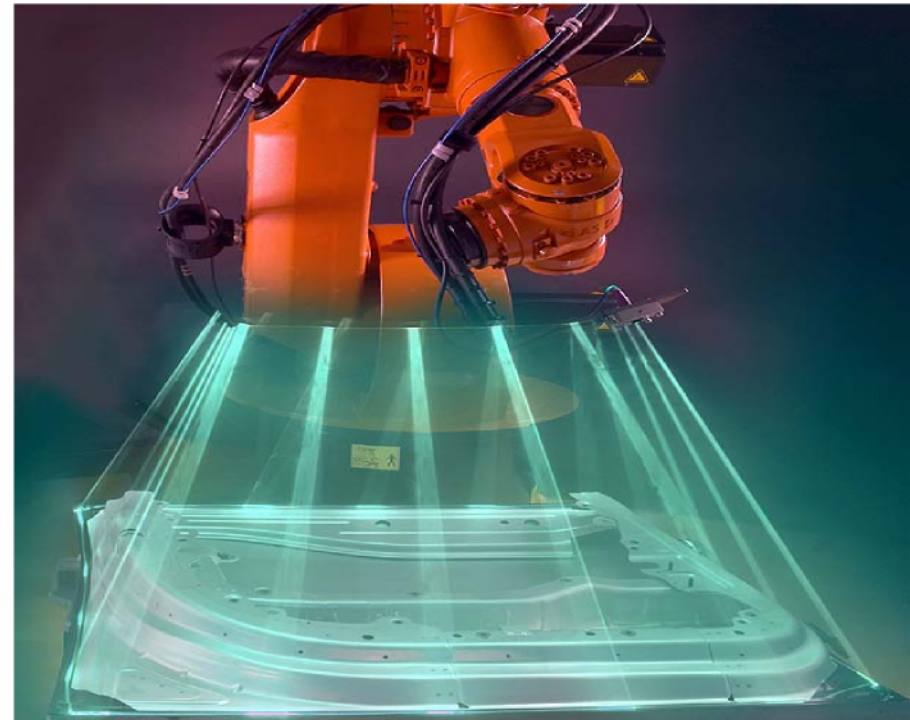
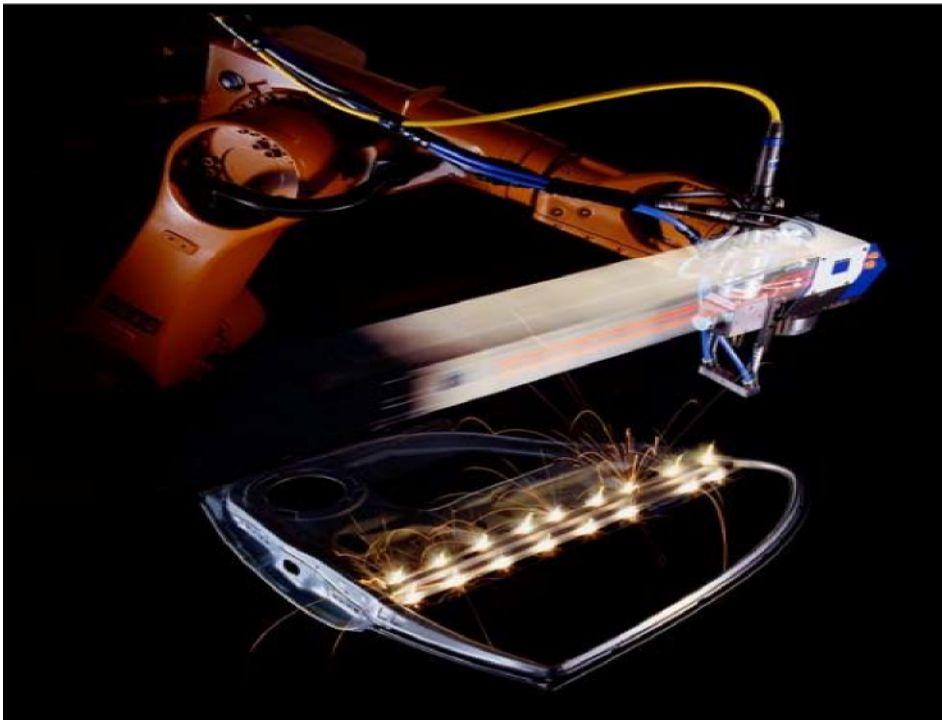
Laserinstitut
Mittelsachsen e.V.



Scanner und KUKA *RoboScan* . *Scanner and KUKA RoboScan*

Bewertungskriterien:

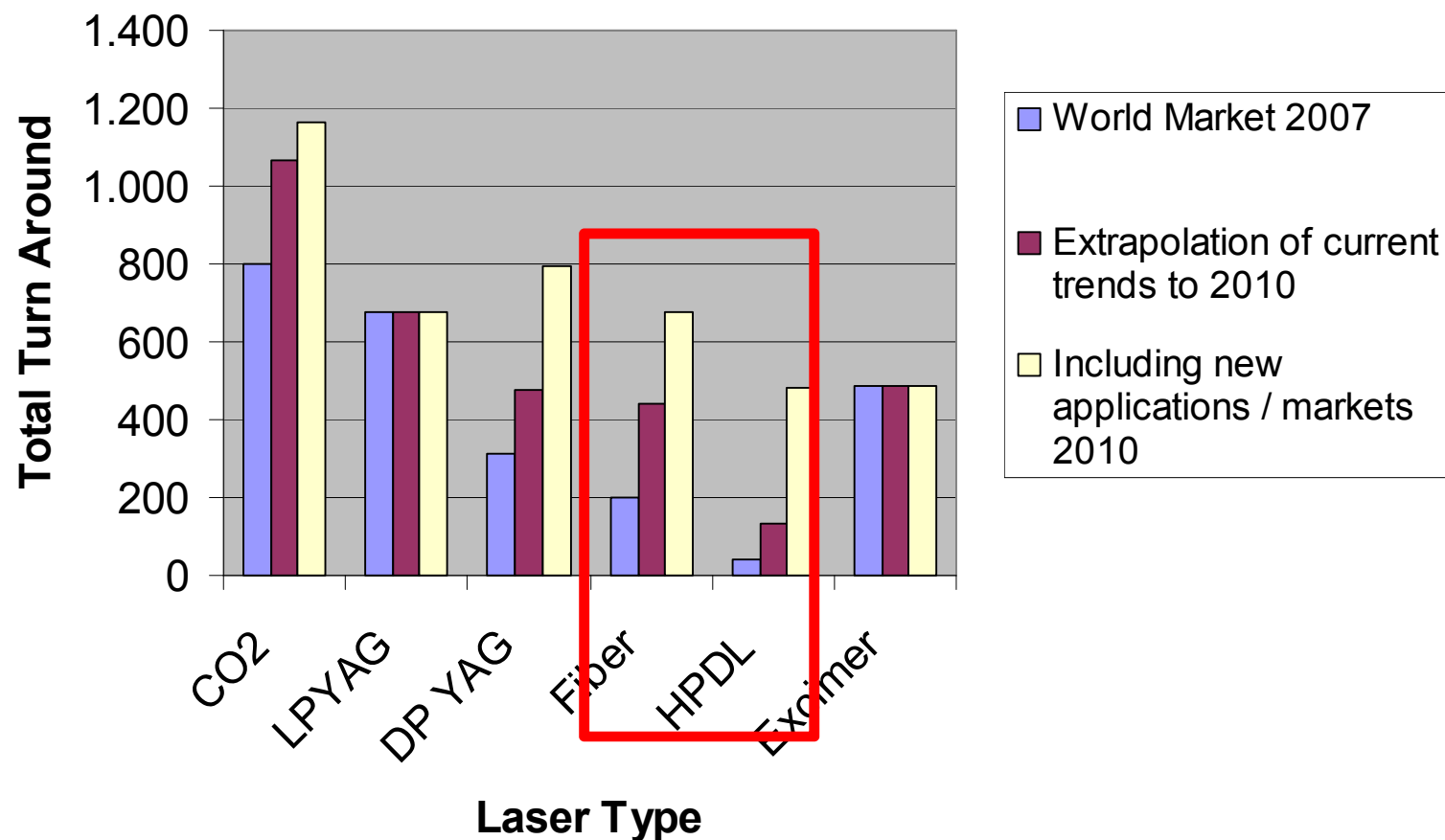
Versatzgeschwindigkeit - Schweißgeschwindigkeit - Taktzeit - Linienkonzept - Komponentenflexibilität - Arbeitsabstand - fixe und variable Kosten - Zugänglichkeit - Nahtgeometrie - Bauteilflexibilität - Lasernutzung - Schweißqualität



Assessment criteria:

cross velocity - welding speed - cycle time - line concepts - flexibility of components - working distance - fix and variable costs - accessibility - seam geometry options - part flexibility - efficiency of laser source usage - weld quality

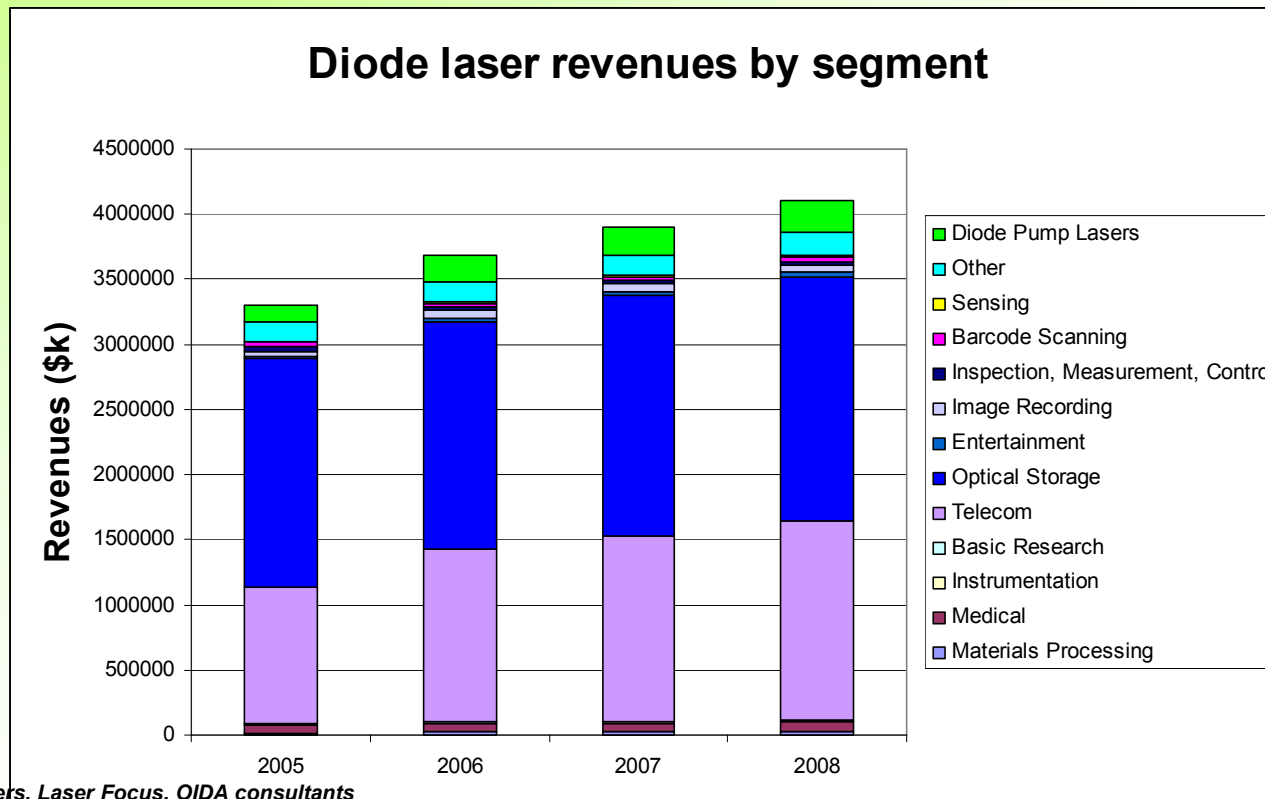
Power Photonics



▪ Source: Prof. Dr. Reinhart Poprawe, ILT (AKL 2008)

Diode laser revenues by application

- Diode pump lasers grow faster than rest



■ Sources: OIDA, OIDA members, Laser Focus, OIDA consultants

■ Michael Leby
(leby@oida.org)



■ Where is the new cash cow?

Direct Diode: Trends

- Power Photonics, all solid state based high power sources will grow much faster than the market.
 - Based on pump diodes, fiber combiners and couples, passive and active fibers
- Classic lasers CW lasers around 1 um (lamped pumped and diode pumped YAG lasers) will be displaced
 - Superior efficiency of direct diode (50% wallplug power conversion) and fiber lasers (30% wallplug power conversion)
- High cw powers will enable new applications (3d cutting, ..)
- Classic lasers (CO2, excimer, ultrashort pulses) will continue to be used based on wavelength and high peak power/short pulse length